

FEATURES

Wideband RF input frequency range: 24 GHz to 44 GHz
2 downconversion modes
 Direct conversion from RF to baseband I/Q
 Image rejecting downconversion to complex IF
LO input frequency range: 5.4 GHz to 10.25 GHz
LO quadrupler for up to 41 GHz
Matched 50 Ω , single-ended RF input, and complex IF outputs
Option between matched 100 Ω balanced or 50 Ω single-ended LO inputs
100 Ω balanced baseband I/Q output impedance with adjustable output common-mode voltage level
Image rejection optimization
Square law power detector for setting mixer input power
Variable attenuator for receiver power control
Programmable via a 4-wire SPI interface
32-terminal, 5 mm $\times$ 5 mm LGA package

APPLICATIONS

Point to point microwave radios
Radar, electronic warfare systems
Instrumentation, automatic test equipment (ATE)

GENERAL DESCRIPTION

The ADMV1014 is a silicon germanium (SiGe), wideband, microwave downconverter optimized for point to point microwave radio designs operating in the 24 GHz to 44 GHz frequency range.

The downconverter offers two modes of frequency translation. The device is capable of direct quadrature demodulation to baseband inphase (I)/quadrature (Q) output signals, as well as image rejection downconversion to a complex intermediate frequency (IF) output carrier frequency. The baseband outputs can be dc-coupled, or, more typically, the I/Q outputs are ac-coupled with a sufficiently low high-pass corner frequency to ensure adequate demodulation accuracy. The serial port interface (SPI) allows fine adjustment of the quadrature phase to allow the user to optimize I/Q demodulation performance. Alternatively, the baseband I/Q outputs can be disabled, and the I/Q signals can be passed through an on-chip active balun to

FUNCTIONAL BLOCK DIAGRAM

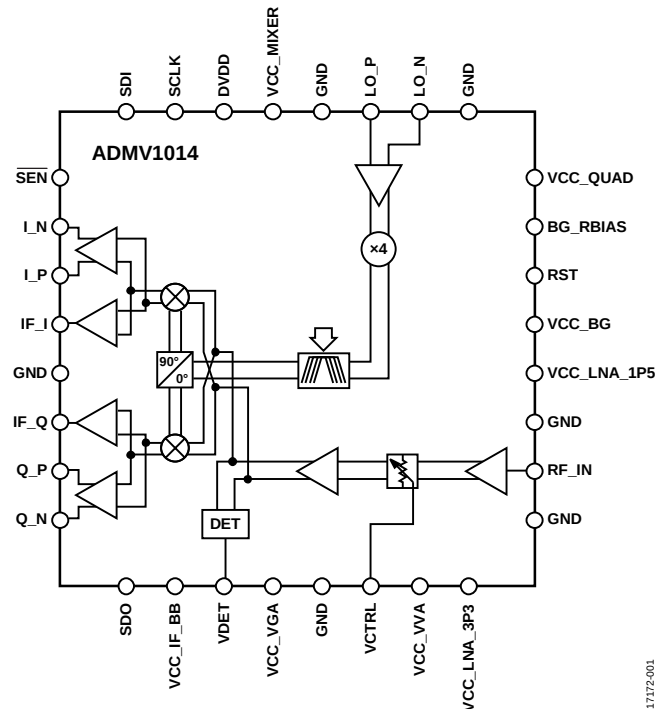


Figure 1.

provide two single-ended complex IF outputs anywhere between 800 MHz and 6000 MHz. When used as an image rejecting downconverter, the unwanted image term is typically suppressed to better than 30 dBc below the wanted sideband. The ADMV1014 offers a flexible local oscillator (LO) system, including a frequency quadruple option allowing up to a 41 GHz range of LO input frequencies to cover a radio frequency (RF) input range as wide as 24 GHz to 44 GHz. A square law power detector is provided to allow monitoring of the power levels at the mixer inputs. The detector output provides closed-loop control of the RF input variable attenuator through an external op amp error integrator circuit option.

The ADMV1014 downconverter comes in a compact, thermally enhanced, 5 mm $\times$ 5 mm LGA package. The ADMV1014 operates over the -40°C to $+85^{\circ}\text{C}$ case temperature range.

TABLE OF CONTENTS

Features	1	Image Rejection Downconversion	29
Applications	1	Detector	29
Functional Block Diagram	1	LO Input Path	29
General Description	1	Power-Down	29
Revision History	2	Serial Port Interface (SPI)	30
Specifications	3	Applications Information	31
Serial Port Register Timing	5	Error Vector Magnitude (EVM) Performance	31
Absolute Maximum Ratings	6	Baseband Quadrature Demodulation to Very Low	
Thermal Resistance	6	Frequencies	32
ESD Caution	6	Performance at Different Quad Filter Settings	32
Pin Configuration and Function Descriptions	7	VVA Temperature Compensation	33
Typical Performance Characteristics	9	Performance Between Differential vs. Single-Ended LO Input	
I/Q Mode	9		33
IF Mode	17	Performance across RF Frequency at Fixed IF and Baseband	
Output Detector Performance	24	Frequencies	34
Return Loss	25	Recommended Land Pattern	35
M × N Spurious Performance	27	Evaluation Board Information	35
Theory of Operation	28	Register Summary	36
Start-Up Sequence	28	Register Details	37
Baseband Quadrature Demodulation (I/Q Mode)	28	Outline Dimensions	42
		Ordering Guide	42

REVISION HISTORY

10/2018—Revision 0: Initial Version

SPECIFICATIONS

RF amplitude = -30 dBm, measurements performed with a 0 mV dc bias. VCC_MIXER = VCC_QUAD = VCC_BG = VCC_LNA = VCC_VGA = VCC_IF_BB = 3.3 V, DVDD = VCC_VVA = 1.8 V, Register 0x0B set to 0x727C, Register 0x03, Bits[12:13] set to 11, and ambient temperature (T_A) = 25°C, unless otherwise noted.

Measurements are in IF mode, performed with a 90° hybrid, Register 0x03, Bit 11 = 0, and Register 0x03, Bit 8 = 1, unless otherwise noted.

Measurements in I/Q mode are measured as a composite of the I and Q channel performance, common-mode voltage (V_{CM}) = 1.15 V, Register 0x03, Bit 11 = 1, and Register 0x03, Bit 8 = 0, unless otherwise noted.

Table 1.

Parameter	Test Conditions/Comments	Min	Typ	Max	Unit
FREQUENCY RANGES					
RF Input		24		44	GHz
LO Input		5.4		10.25	GHz
LO Quadrupler		21.6		41	GHz
IF Output		0.8		6.0	GHz
Baseband (BB) I/Q Output		DC		6.0	GHz
LO AMPLITUDE RANGE		-6	0	+6	dBm
I/Q DEMODULATOR PERFORMANCE					
Conversion Gain	At maximum gain				
24 GHz to 42 GHz		12.5	17		dB
42 GHz to 44 GHz		12.5	17		dB
Voltage Variable Attenuator (VVA) Control Range			19		dB
Single Sideband (SSB) Noise Figure	At maximum gain				
24 GHz to 42 GHz			5.5	8	dB
42 GHz to 44 GHz			6	8.5	dB
Input Third-Order Intercept (IP3)	At maximum gain				
24 GHz to 42 GHz			0		dBm
42 GHz to 44 GHz			-1		dBm
Input Second-Order Intercept (IP2)	24 GHz to 44 GHz, at maximum gain		45		dBm
Input 1 dB Compression Point (P1dB)	At maximum gain				
24 GHz to 42 GHz		-14	-10		dBm
42 GHz to 44 GHz		-15	-11		dBm
Amplitude Balance			±0.5		dB
Phase Balance	DC < baseband frequency (f_{BB}) < 2 GHz		1		Degrees
	2 GHz < f_{BB} < 4 GHz		2		Degrees
	4 GHz < f_{BB} < 6 GHz		4		Degrees
Image Rejection	24 GHz to 44 GHz, at maximum gain				
Uncalibrated			45		dBc
Calibrated			52		dBc
IF DOWNCONVERTER PERFORMANCE					
Conversion Gain	At maximum gain				
24 GHz to 42 GHz		12.5	17		dB
42 GHz to 44 GHz		11.5	16		dB
VVA Control Range			19		dB
SSB Noise Figure	At maximum gain				
24 GHz to 42 GHz			5.5	8	dB
42 GHz to 44 GHz			6	8.5	dB
Input IP3	At maximum gain				
24 GHz to 42 GHz			0		dBm
42 GHz to 44 GHz			0.5		dBm

Parameter	Test Conditions/Comments	Min	Typ	Max	Unit
Input P1dB	At maximum gain	–14	–9		dBm
24 GHz to 42 GHz		–15	–10		dBm
42 GHz to 44 GHz			–0.5		dB
Amplitude Balance			0.5		Degrees
Phase Balance	800 MHz < IF frequency (f_{IF}) < 2 GHz		1		Degrees
	2 GHz < f_{IF} < 4 GHz		2.5		Degrees
	4 GHz < f_{IF} < 6 GHz				Degrees
Image Rejection			30		dBc
Uncalibrated			35		dBc
Calibrated					dBc
RECEIVER (Rx) POWER DETECTOR PERFORMANCE					
Input Level	±1 dB dynamic range				
Minimum			–35		dBm
Maximum			–14		dBm
±1 dB Dynamic Range			20		dB
Output Voltage					
Maximum DC Output			3.3		V
RETURN LOSS					
RF Input	50 Ω single-ended		–13		dB
LO Input	100 Ω differential		–10		dB
IF Output	50 Ω single-ended		–12		dB
BB Output	100 Ω differential		–15		dB
BB I/Q Output Impedance			100		Ω
LEAKAGE					
Fundamental LO to RF	At maximum gain		–70		dBm
4 × LO to RF			–70		dBm
Fundamental LO to IF			–60		dBm
Fundamental LO to I/Q			–60		dBm
LOGIC INPUTS					
Input Voltage Range					
High, V_{INH}		DVDD – 0.4		1.8	V
Low, V_{INL}		0		0.4	V
Input Current, I_{INH}/I_{INL}			100		μ A
Input Capacitance, C_{IN}			3		pF
LOGIC OUTPUTS					
Output Voltage Range					
High, V_{OH}		DVDD – 0.4		1.8	V
Low, V_{OL}		0		0.4	V
Output High Current, I_{OH}				500	μ A
POWER INTERFACE					
VCC_IF_BB, VCC_VGA, VCC_LNA_3P3, VCC_MIXER, VCC_BG, VCC_QUAD		3.15	3.3	3.45	V
3.3 V Supply Current			437		mA
DVDD, VCC_VVA		1.7	1.8	1.9	V
1.8 V Supply Current			4.2		mA
VCC_LNA_1P5		1.43	1.5	1.57	V
1.5 V Supply Current			33		mA
Total Power Consumption			1.5		W
Power-Down			96	125	mW

SERIAL PORT REGISTER TIMING

Table 2.

Parameter	Description	Min	Typ	Max	Unit
$t_{SDI, SETUP}$	Data to clock setup time	10			ns
$t_{SDI, HOLD}$	Data to clock hold time	10			ns
$t_{SCLK, HIGH}$	Clock high duration	40 to 60			%
$t_{SCLK, LOW}$	Clock low duration	40 to 60			%
$t_{SCLK, \overline{SEN}_{SETUP}}$	Clock to $\overline{SEN}$ setup time	30			ns
$t_{SCLK, DOT}$	Clock to data out transition time			10	ns
$t_{SCLK, DOV}$	Clock to data out valid time			10	ns
$t_{SCLK, \overline{SEN}_{INACTIVE}}$	Clock to $\overline{SEN}$ inactive	20			ns
$t_{\overline{SEN}_{INACTIVE}}$	Inactive $\overline{SEN}$ (between two operations)	80			ns

Timing Diagram

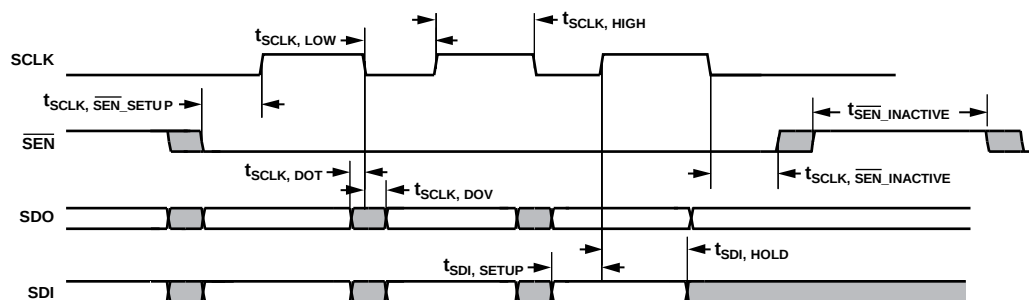


Figure 2. Serial Port Register Timing Diagram

17172-106

ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
Supply Voltage	
VCC_IF_BB, VCC_VGA, VCC_LNA_3P3, VCC_MIXER, VCC_BG, VCC_QUAD, DVDD	4.3 V
VCC_VVA, VCC_LNA_1P5	2.3 V
RF Input Power	0 dBm
LO Input Power	9 dBm
Maximum Junction Temperature	125°C
Maximum Power Dissipation ¹	2.9 W
Lifetime at Maximum Junction Temperature (T _J)	1 × 10 ⁶ hours
Operating Case Temperature Range	–40°C to +85°C
Storage Temperature Range	–55°C to +125°C
Lead Temperature (Soldering 60 sec)	260°C
Moisture Sensitivity Level (MSL) Rating ²	MSL3
Electrostatic Discharge (ESD) Sensitivity	
Human Body Model (HBM)	3000 V
Field Induced Charged Device Model (FICDM)	750 V

¹ The maximum power dissipation is a theoretical number calculated by $(T_J - 85^\circ\text{C})/\theta_{JC_TOP}$.

² Based on IPC/JEDEC J-STD-20 MSL classifications.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

θ_{JA} is the natural convection junction to ambient thermal resistance measured in a one cubic foot sealed enclosure. θ_{JC} is the junction to case thermal resistance.

Table 4. Thermal Resistance

Package Type ¹	θ_{JA} ²	θ_{JC_TOP} ³	θ_{JB} ⁴	Ψ_{JT} ⁵	Ψ_{JB} ⁶	Unit
CC-32-6	33.6	18.4	13.3	4.9	12.6	°C/W

¹ The thermal resistance values specified in Table 4 are simulated based on JEDEC specifications, unless specified otherwise, and must be used in compliance with JESD51-12.

² θ_{JA} is the junction to ambient thermal resistance in a natural convection, JEDEC environment.

³ θ_{JC_TOP} is the junction to case (top) JEDEC thermal resistance.

⁴ θ_{JB} is the junction to board JEDEC thermal resistance.

⁵ Ψ_{JT} is the junction to top JEDEC thermal characterization parameter.

⁶ Ψ_{JB} is the junction to board JEDEC thermal characterization parameter

ESD CAUTION



ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

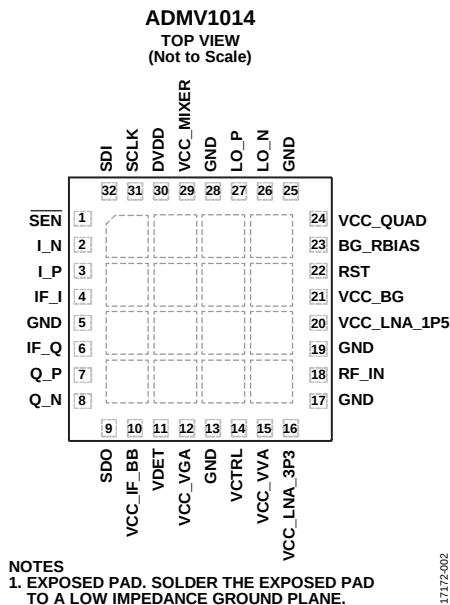


Figure 3. Pin Configuration

Table 4. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	SEN	SPI Serial Enable. SEN is a high impedance pin with a logic of 1.8 V.
2, 3	I_N, I_P	Negative (I_N) and Positive (I_P) Differential BB I Outputs. These pins are dc-coupled.
4, 6	IF_I, IF_Q	IF I and IF Q Single-Ended Complex Quadrature Outputs. These pins are dc-coupled to GND, and each pin is matched to 50 Ω .
5, 13, 17, 19, 25, 28	GND	Ground.
7, 8	Q_P, Q_N	Positive (Q_P) and Negative (Q_N) Differential Baseband Q Outputs. These pins are dc-coupled.
9	SDO	SPI Serial Data Output.
10	VCC_IF_BB	3.3 V Power Supply for BB and IF Section. Place a 100 pF, 0.01 μ F, and a 10 μ F capacitor close to this pin.
11	VDET	Square Law Detector Output Voltage.
12	VCC_VGA	3.3 V Power Supply for RF Amplifier. Place a 100 pF, 0.01 μ F, and a 10 μ F capacitor close to this pin.
14	VCTRL	RF VVA Control Voltage. The voltage on this pin ranges from 1.8 V (minimum gain) to 0 V (maximum gain). Refer to the ADMV1014-EVALZ user guide for the external component requirements.
15	VCC_VVA	1.8 V Power Supply for VVA Control Circuit. Place a 100 pF, 0.01 μ F, and a 10 μ F capacitor close to this pin.
16	VCC_LNA_3P3	3.3 V Power Supply for LNA. Place a 100 pF, 0.01 μ F, and a 10 μ F capacitor close to this pin.
18	RF_IN	RF Input. This pin is dc-coupled internally with a choke to GND, and matched to 50 Ω , single-ended. A dc input above 0 V requires external ac coupling.
20	VCC_LNA_1P5	1.5 V Power Supply for Low Noise Amplifier (LNA). Place a 100 pF, 0.01 μ F, and a 10 μ F capacitor close to this pin.
21	VCC_BG	3.3 V Power Supply for Band Gap Circuit. Place a 100 pF, 0.01 μ F, and a 10 μ F capacitor close to this pin.
22	RST	SPI Reset. Connect this pin to logic high for normal operation.
23	BG_RBIAS	Bang Gap Circuit External High Precision Resistor. Place a 1.1 k Ω , high precision resistor shunt to ground close to this pin.
24	VCC_QUAD	3.3 V Power Supply for Quadruple. Place a 100 pF, 0.01 μ F, and a 10 μ F capacitor close to this pin.
26, 27	LO_N, LO_P	Negative (LO_N) and Positive (LO_P) Differential Local Oscillator Input. These pins are dc-coupled internally with a choke to GND and matched to 100 Ω differential or 50 Ω single-ended. A dc input above 0 V requires external ac coupling.
29	VCC_MIXER	3.3 V Power Supply for the Mixer. Place a 100 pF, 0.01 μ F, and a 10 μ F capacitor close to this pin.
30	DVDD	1.8 V SPI Digital Supply. Place a 100 pF, 0.01 μ F, and a 10 μ F capacitor close to this pin.

31	SCLK	SPI Clock Digital Input. SCLK is a high impedance pin.
32	SDI	SPI Serial Data Input. SDI is a high impedance pin.
	EPAD	Exposed Pad. Solder the exposed pad to a low impedance ground plane.

TYPICAL PERFORMANCE CHARACTERISTICS

I/Q MODE

RF amplitude = -30 dBm, measurements performed with a 0 mV dc bias. $V_{CC_MIXER} = V_{CC_QUAD} = V_{CC_BG} = V_{CC_LNA} = V_{CC_VGA} = V_{CC_IF_BB} = 3.3$ V, $DVDD = V_{CC_VVA} = 1.8$ V, and $T_A = 25^\circ\text{C}$, unless otherwise noted. Register 0x0B is set to 0x727C, Register 0x03, Bits[13:12] are set to 11, $V_{CM} = 1.15$ V, Register 0x03, Bit 11 = 1, Register 0x03, Bit 8 = 0, and measurements are a composite of the I and Q channels. V_{ATT} is the attenuation voltage at the VCTRL pin. $V_{ATT} = 0$ V, unless otherwise specified.

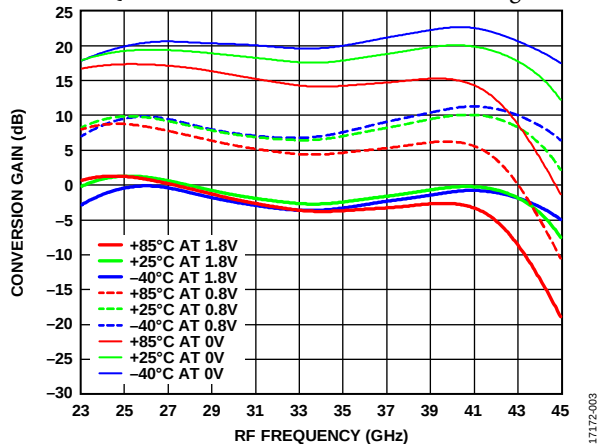


Figure 4. Conversion Gain vs. RF Frequency at Three Different Gain Settings for Various Temperatures, $f_{BB} = 100$ MHz (Upper Sideband)

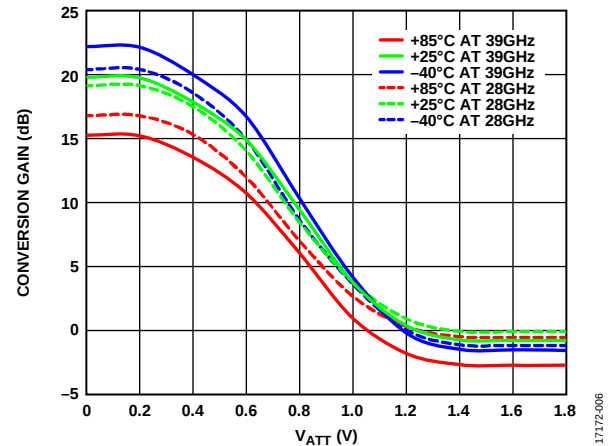


Figure 7. Conversion Gain vs. V_{ATT} for Various RF Frequencies (f_{RF}), $f_{BB} = 100$ MHz at $f_{RF} = 28$ GHz and 39 GHz

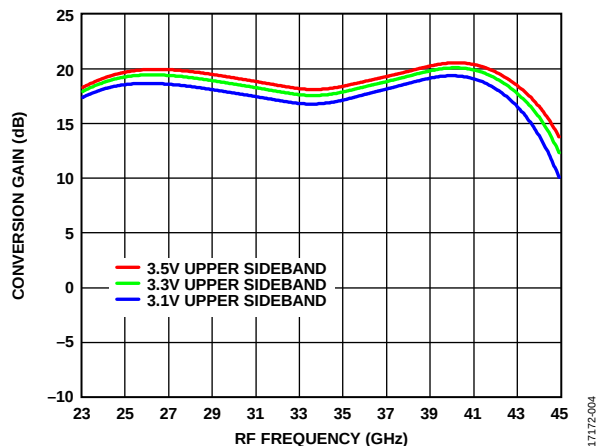


Figure 5. Conversion Gain vs. RF Frequency for Various Supply Voltages, $f_{BB} = 100$ MHz

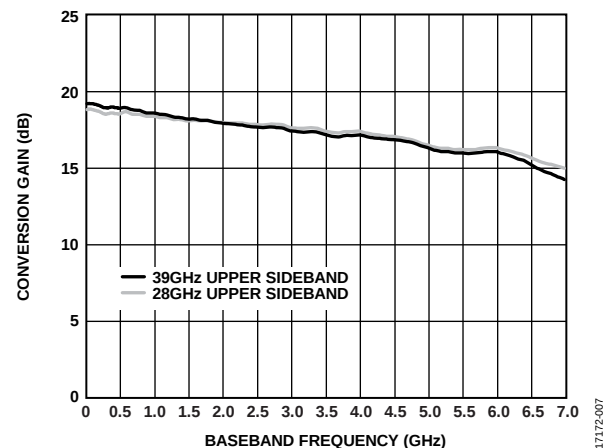


Figure 8. Conversion Gain vs. Baseband Frequency at $f_{RF} = 28$ GHz and 39 GHz (Upper Sideband)

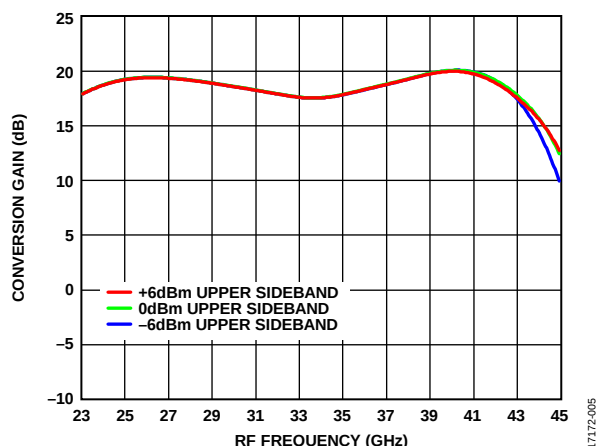


Figure 6. Conversion Gain vs. RF Frequency for Various LO Inputs, $f_{BB} = 100$ MHz

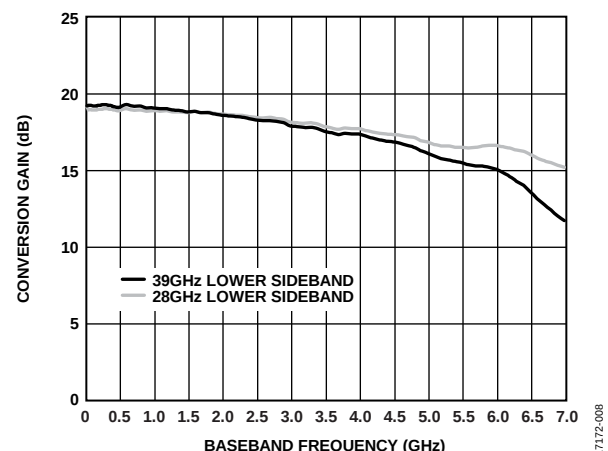


Figure 9. Conversion Gain vs. Baseband Frequency at $f_{RF} = 28$ GHz and 39 GHz (Lower Sideband)

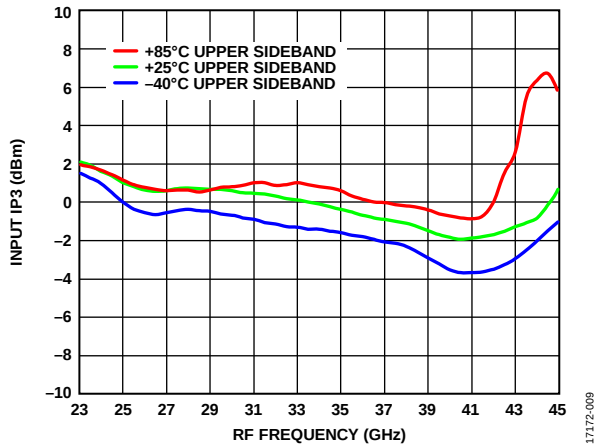


Figure 10. Input IP3 vs. RF Frequency at Maximum Gain for Various Temperatures, RF Amplitude = -30 dBm per Tone at 20 MHz Spacing, $f_{BB} = 100$ MHz (Upper Sideband)

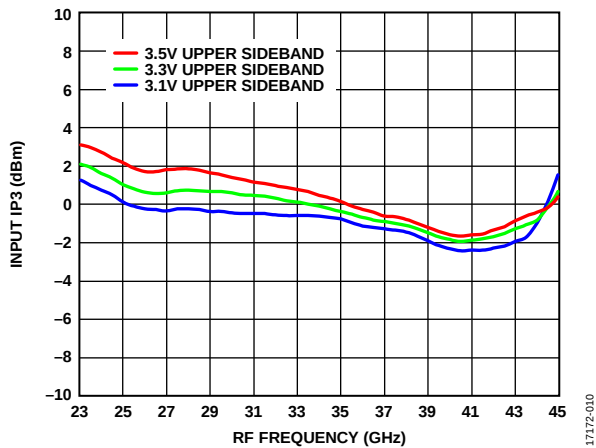


Figure 11. Input IP3 vs. RF Frequency at Maximum Gain for Various Supply Voltages, RF Amplitude = -30 dBm per Tone at 20 MHz Spacing, $f_{BB} = 100$ MHz (Upper Sideband)

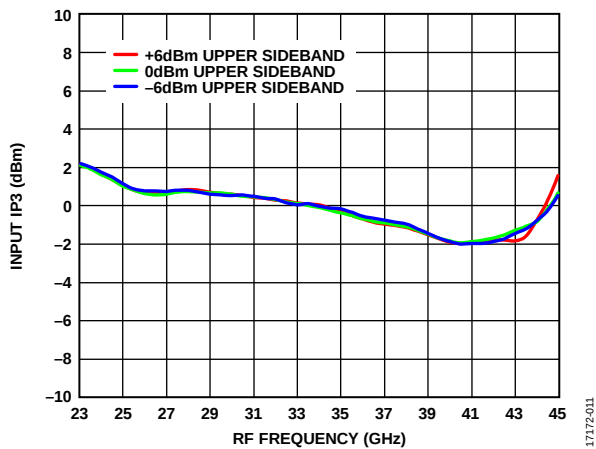


Figure 12. Input IP3 vs. RF Frequency at Maximum Gain for Various LO Inputs, RF Amplitude = -30 dBm per Tone at 20 MHz Spacing, $f_{BB} = 100$ MHz (Upper Sideband)

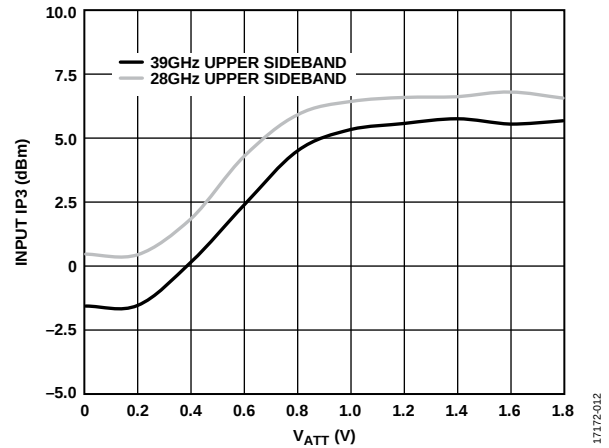


Figure 13. Input IP3 vs. V_{ATT} for Various RF Frequencies (f_{RF}), RF Amplitude = -30 dBm per Tone at 20 MHz Spacing, $f_{BB} = 100$ MHz (Upper Sideband) at $f_{RF} = 28$ GHz and 39 GHz

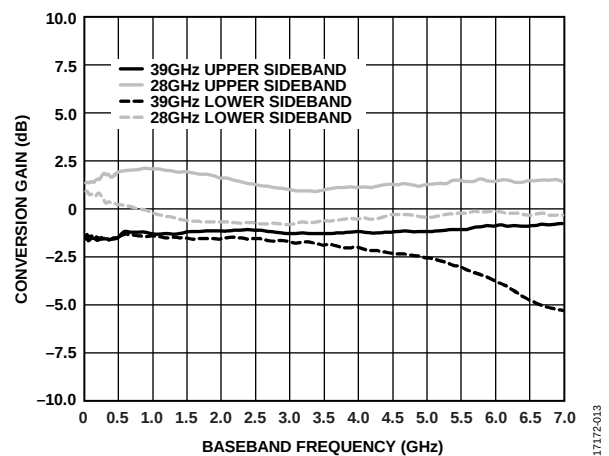


Figure 14. Conversion Gain vs. Baseband Frequency at Maximum Gain, RF Amplitude = -30 dBm per Tone at 20 MHz Spacing at $f_{RF} = 28$ GHz and 39 GHz, Upper Sideband and Lower Sideband

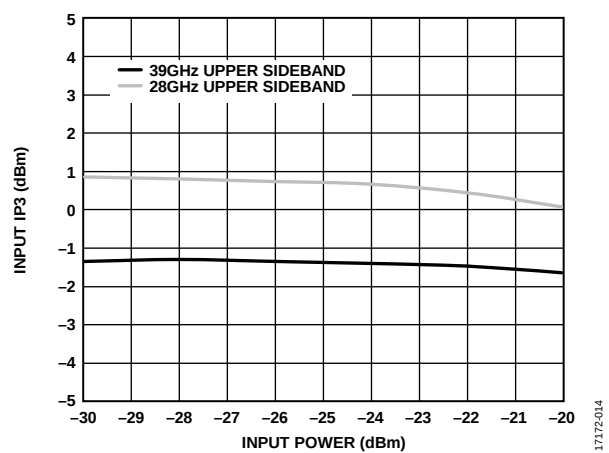


Figure 15. Input IP3 vs. Input Power for Various RF Frequencies (f_{RF}) at 20 MHz Spacing, $f_{BB} = 100$ MHz, $f_{RF} = 28$ GHz and 39 GHz

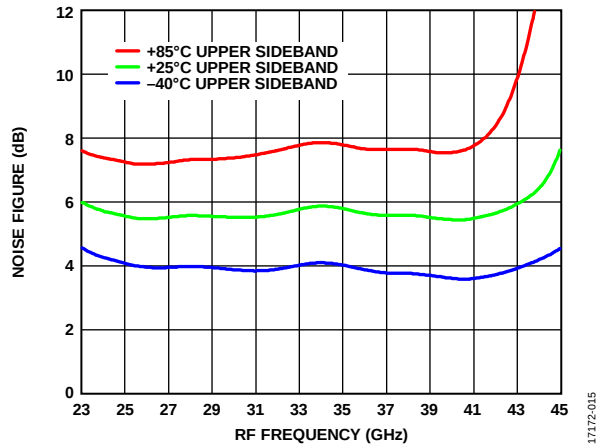


Figure 16. Noise Figure vs. RF Frequency at Maximum Gain for Various Temperatures, $f_{BB} = 100$ MHz

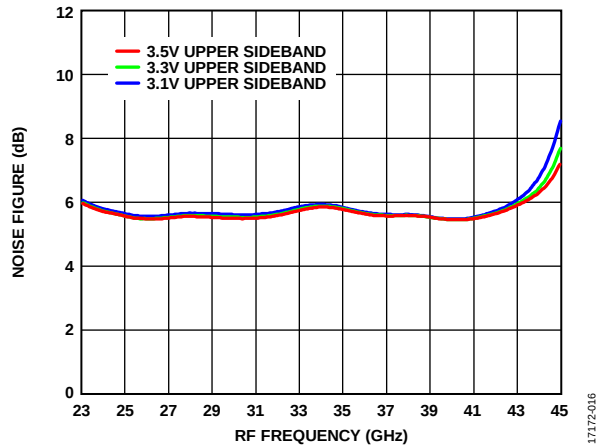


Figure 17. Noise Figure vs. RF Frequency for Various Supply Voltages, $f_{BB} = 100$ MHz

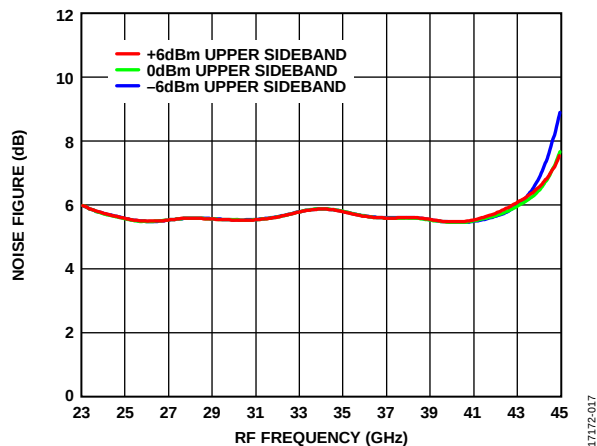


Figure 18. Noise Figure vs. RF Frequency for Various LO Inputs, $f_{BB} = 100$ MHz

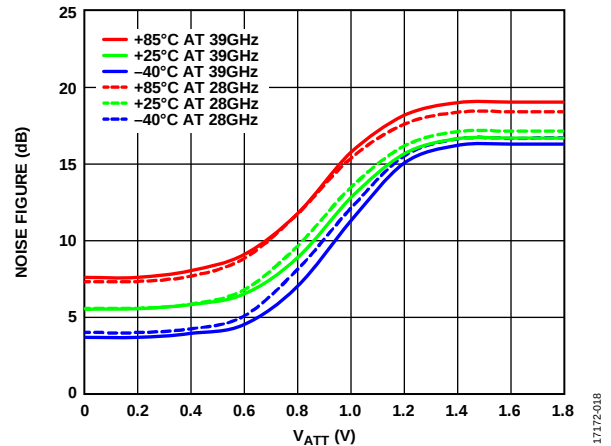


Figure 19. Noise Figure vs. V_{ATT} for Various RF Frequencies, $f_{BB} = 100$ MHz at $f_{RF} = 28$ GHz and 39 GHz

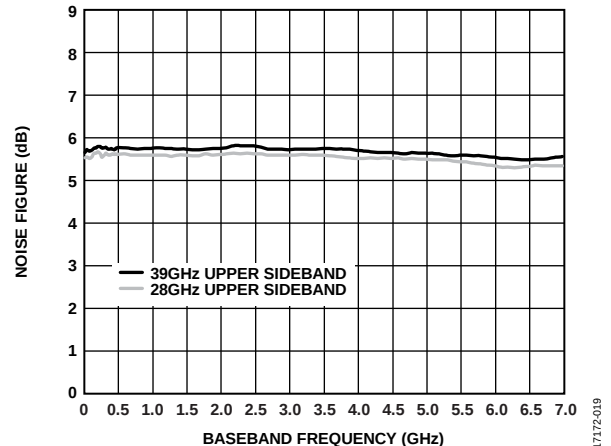


Figure 20. Noise Figure vs. Baseband Frequency at $f_{RF} = 28$ GHz and 39 GHz (Upper Sideband)

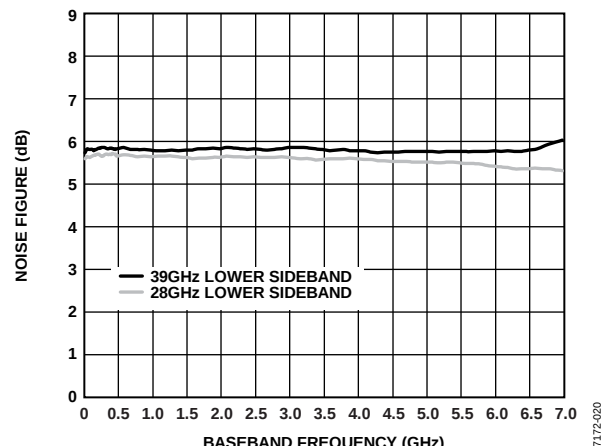


Figure 21. Noise Figure vs. Baseband Frequency at $f_{RF} = 28$ GHz and 39 GHz (Lower Sideband)

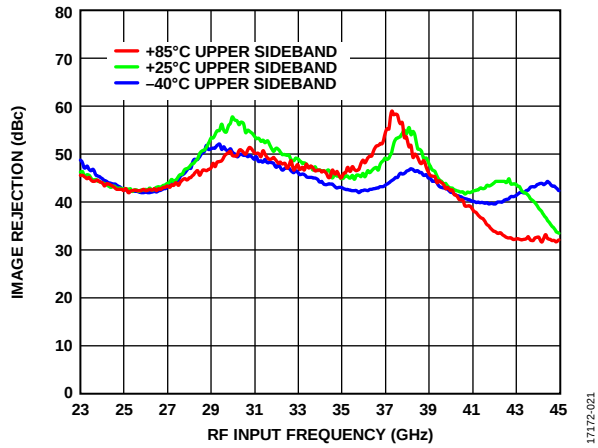


Figure 22. Image Rejection vs. RF Input Frequency at Maximum Gain for Various Temperatures, $f_{BB} = 100$ MHz, Uncalibrated

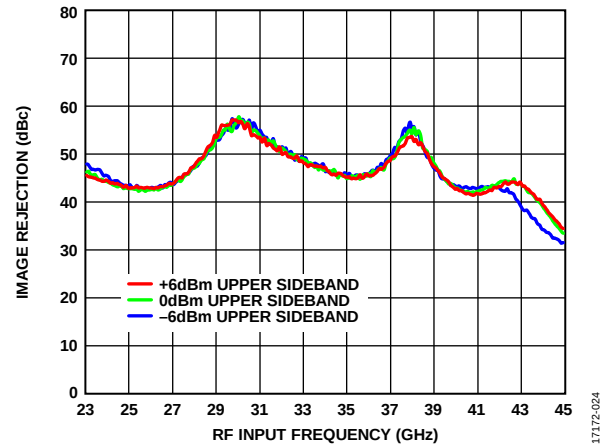


Figure 25. Image Rejection vs. RF Input Frequency for Various LO Inputs, $f_{BB} = 100$ MHz

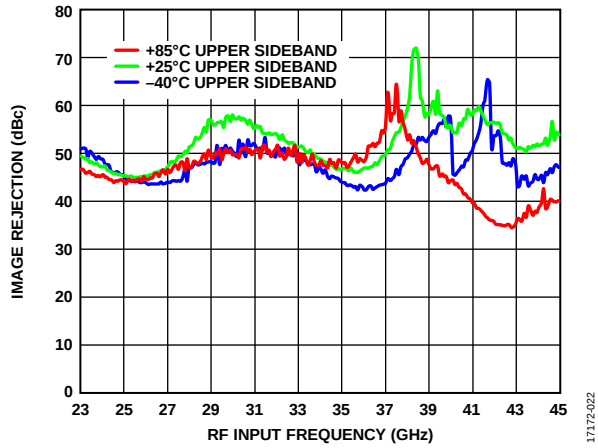


Figure 23. Image Rejection vs. RF Input Frequency at Maximum Gain for Various Temperatures, $f_{BB} = 100$ MHz, Calibrated

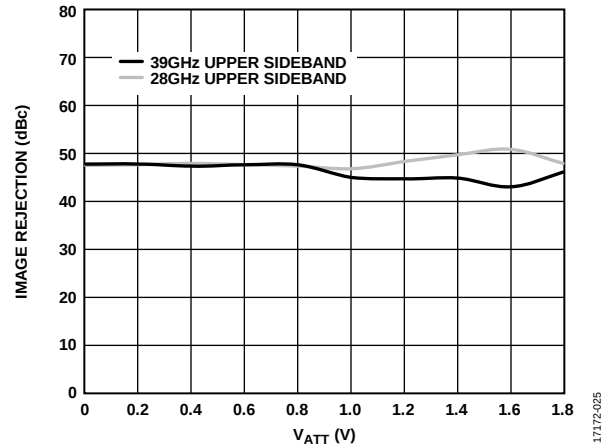


Figure 26. Image Rejection vs. V_{ATT} for Various RF Frequencies (f_{RF}), $f_{BB} = 100$ MHz at $f_{RF} = 28$ GHz and 39 GHz

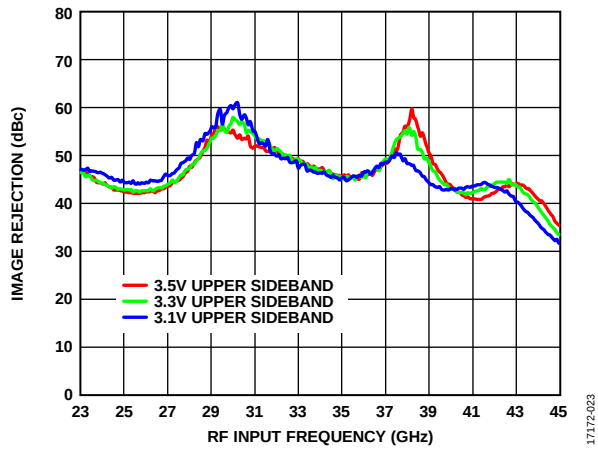


Figure 24. Image Rejection vs. RF Input Frequency for Various Supply Voltages, $f_{BB} = 100$ MHz

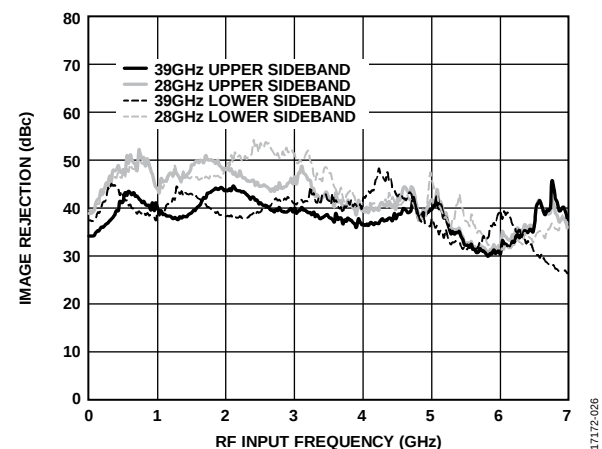


Figure 27. Image Rejection vs. RF Input Frequency at $f_{RF} = 28$ GHz and 39 GHz (Upper Sideband and Lower Sideband)

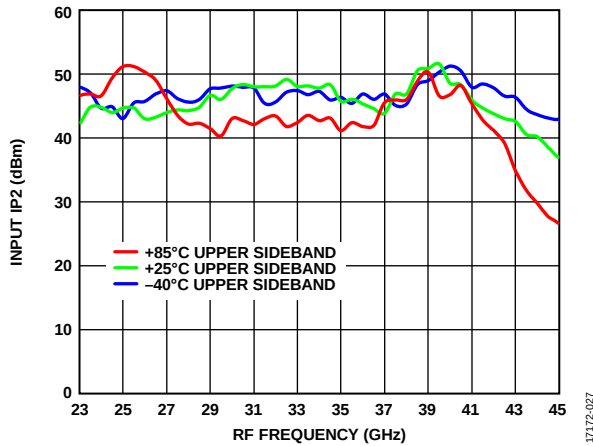


Figure 28. Input IP2 vs. RF Frequency at Maximum Gain for Various Temperatures, RF Amplitude = -30 dBm per Tone at 20 MHz Spacing, $f_{BB} = 100$ MHz (Upper Sideband)

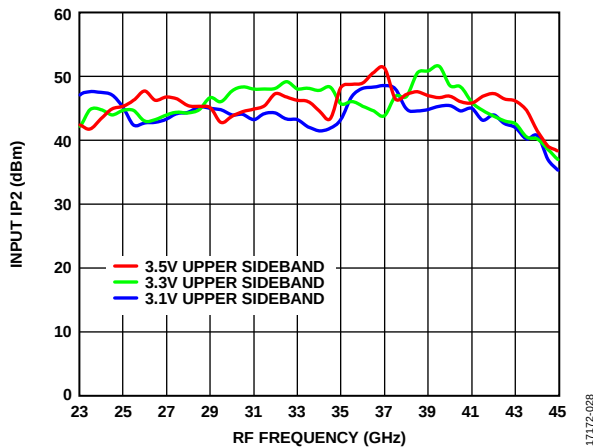


Figure 29. Input IP2 vs. RF Frequency (f_{RF}) at Maximum Gain for Various Supply Voltages, RF Amplitude = -30 dBm per Tone at 20 MHz Spacing, $f_{BB} = 100$ MHz (Upper Sideband)

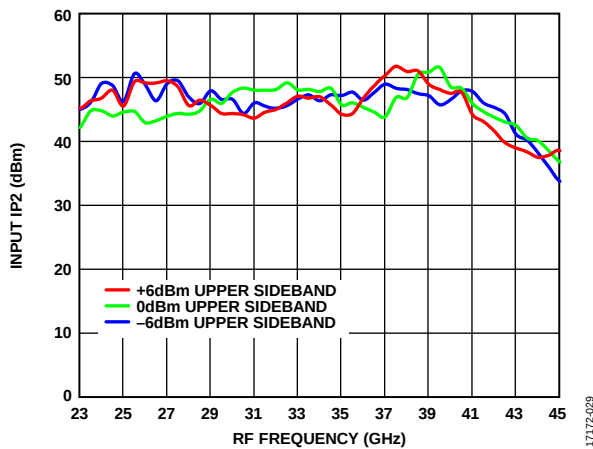


Figure 30. Input IP2 vs. RF Frequency at Maximum Gain for Various LO Inputs, RF Amplitude = -30 dBm per Tone at 20 MHz Spacing, $f_{BB} = 100$ MHz (Upper Sideband)

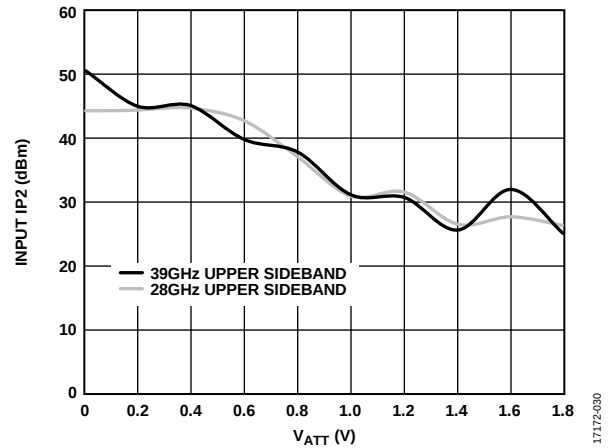


Figure 31. Input IP2 vs. V_{ATT} for Various RF Frequencies (f_{RF}), RF Amplitude = -30 dBm per Tone at 20 MHz Spacing, $f_{BB} = 100$ MHz (Upper Sideband) at $f_{RF} = 28$ GHz and 39 GHz

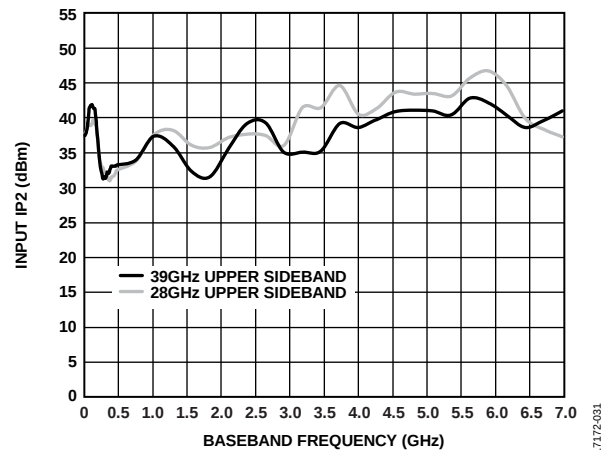


Figure 32. Input IP2 vs. Baseband Frequency at Maximum Gain, RF Amplitude = -30 dBm per Tone at 20 MHz Spacing at $f_{RF} = 28$ GHz and 39 GHz, Upper Sideband

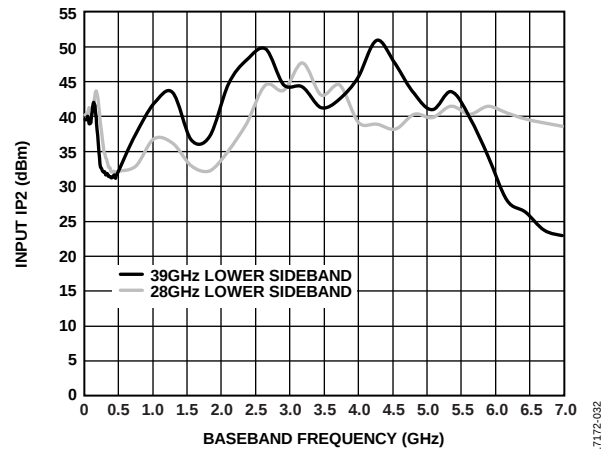


Figure 33. Input IP2 vs. Baseband Frequency for Various RF Frequencies (f_{RF}) at 20 MHz Spacing, $f_{BB} = 100$ MHz, $f_{RF} = 28$ GHz and 39 GHz

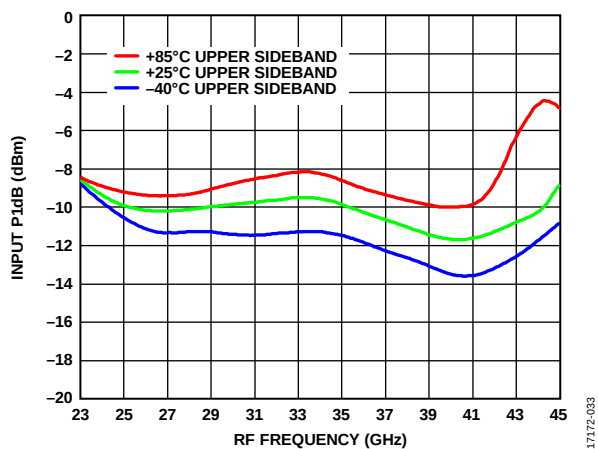


Figure 34. Input P1dB vs. RF Frequency at Maximum Gain for Various Temperatures, $f_{BB} = 100$ MHz

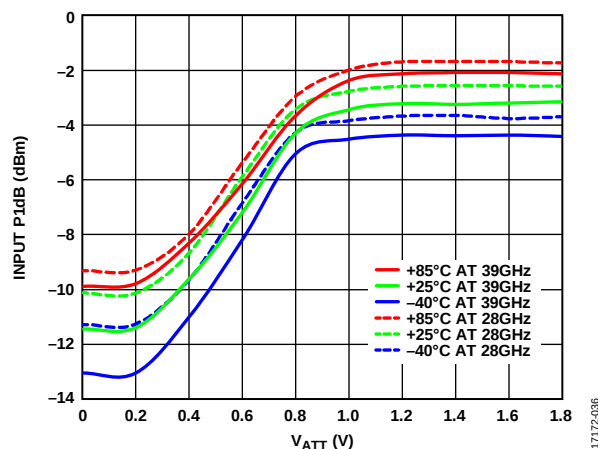


Figure 37. Input P1dB vs. V_{ATT} for Various RF Frequencies (f_{RF}), $f_{BB} = 100$ MHz at $f_{RF} = 28$ GHz and 39 GHz

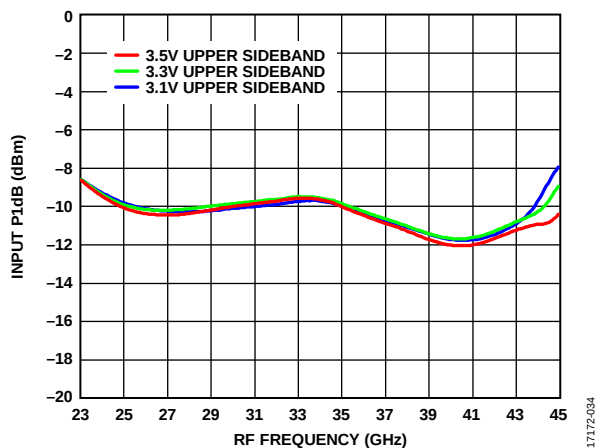


Figure 35. Input P1dB vs. RF Frequency for Various Supply Voltages, $f_{BB} = 100$ MHz

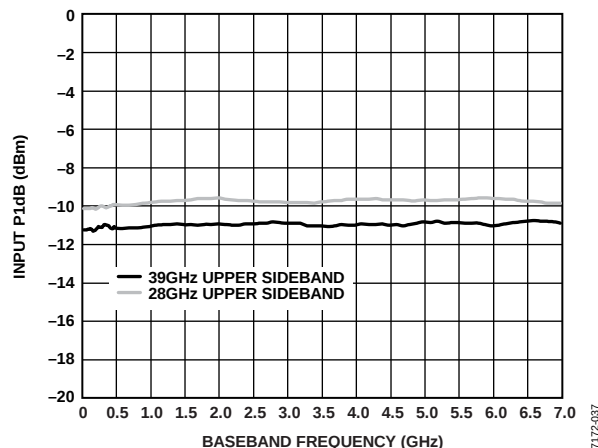


Figure 38. Input P1dB vs. Baseband Output Frequency at $f_{RF} = 28$ GHz and 39 GHz (Upper Sideband)

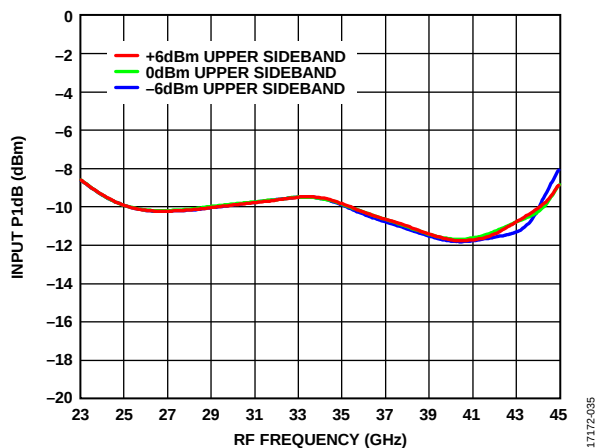


Figure 36. Input P1dB vs. RF Frequency for Various LO Inputs, $f_{BB} = 100$ MHz

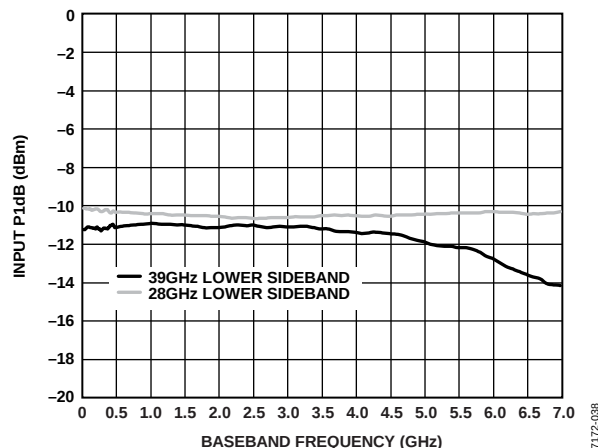


Figure 39. Input P1dB vs. Baseband Output Frequency at $f_{RF} = 28$ GHz and 39 GHz (Lower Sideband)

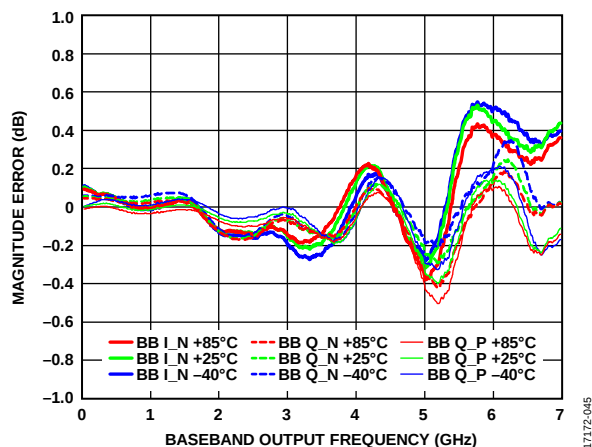


Figure 40. Magnitude Error vs. Baseband Output Frequency, Referenced to I_P Output, $f_{RF} = 28$ GHz, for Various Temperatures, at Maximum Gain

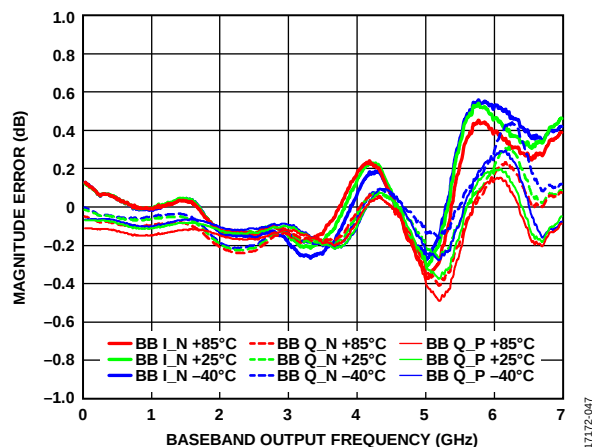


Figure 42. Magnitude Error vs. Baseband Output Frequency, Referenced to I_P Output, $f_{RF} = 39$ GHz, for Various Temperatures, at Maximum Gain

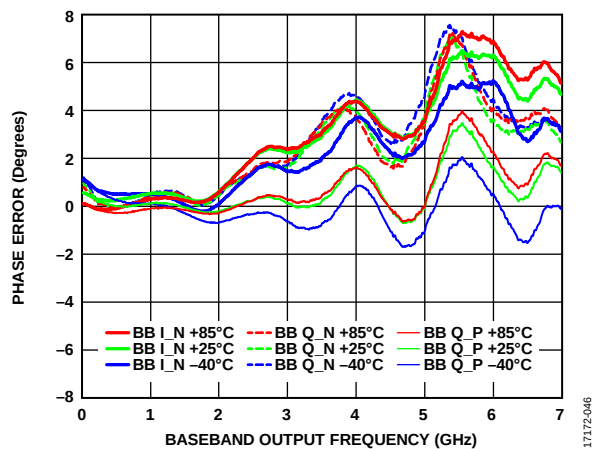


Figure 41. Phase Error vs. Baseband Output Frequency, Referenced to I_P Output, $f_{RF} = 28$ GHz, for Various Temperatures, at Maximum Gain

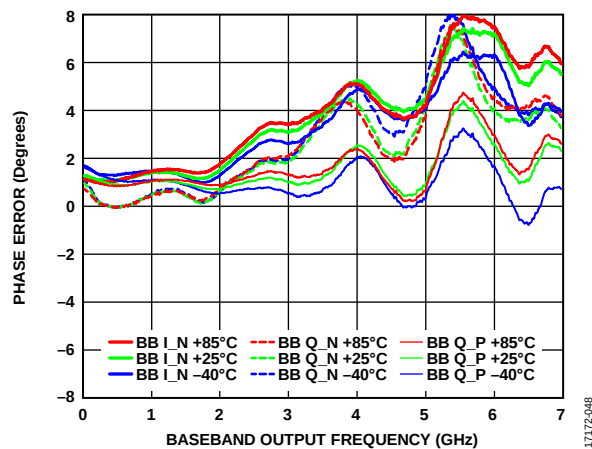


Figure 43. Phase Error vs. Baseband Output Frequency, Referenced to I_P Output, $f_{RF} = 39$ GHz, for Various Temperatures, at Maximum Gain

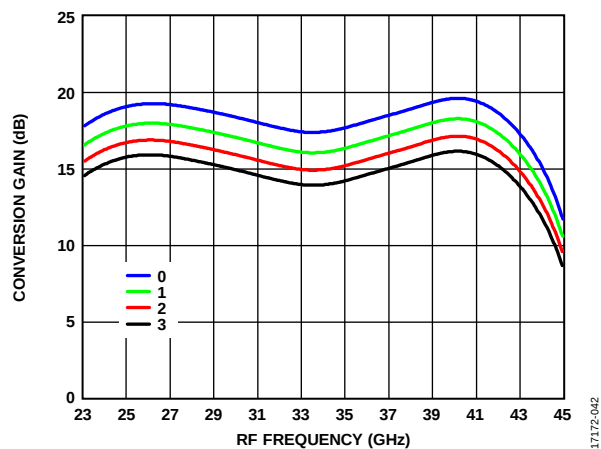


Figure 44. Conversion Gain vs. RF Frequency at Four Different BB_AMP_GAIN_CTRL (Register 0x0A, Bits[2:1]) Settings, $f_{BB} = 100$ MHz (Upper Sideband)

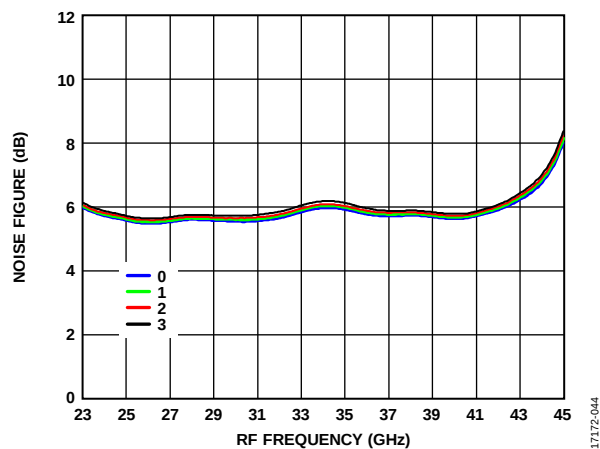


Figure 46. Noise Figure vs. RF Frequency Four Different BB_AMP_GAIN_CTRL (Register 0x0A, Bits[2:1]) Settings, $f_{BB} = 100$ MHz (Upper Sideband)

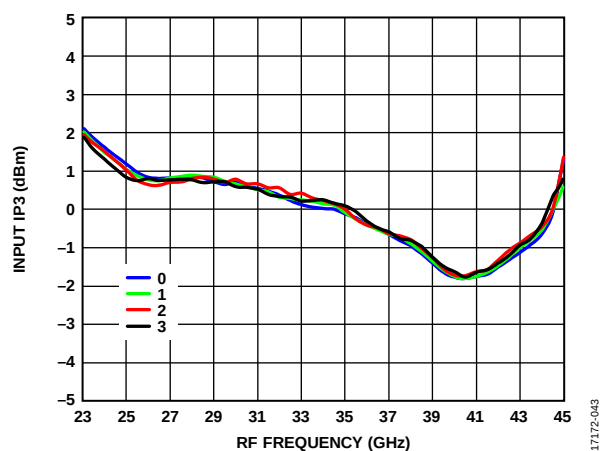


Figure 45. Input IP3 vs. RF Frequency at Four Different BB_AMP_GAIN_CTRL (Register A, Bits[2:1]) Settings, $f_{BB} = 100$ MHz (Upper Sideband)

IF MODE

RF amplitude = -30 dBm, measurements performed with a 0 mV dc bias. $V_{CC_MIXER} = V_{CC_QUAD} = V_{CC_BG} = V_{CC_LNA} = V_{CC_VGA} = V_{CC_IF_BB} = 3.3$ V, $DVDD = V_{CC_VVA} = 1.8$ V, $T_A = 25^\circ\text{C}$ unless otherwise specified. Register 0x0B set to 0x727C, Register 0x03, Bits[12:13] set to 11, measurements performed with a 90° hybrid, Register 0x03, Bit 11 = 0, and Register 0x03, Bit 8 = 1.

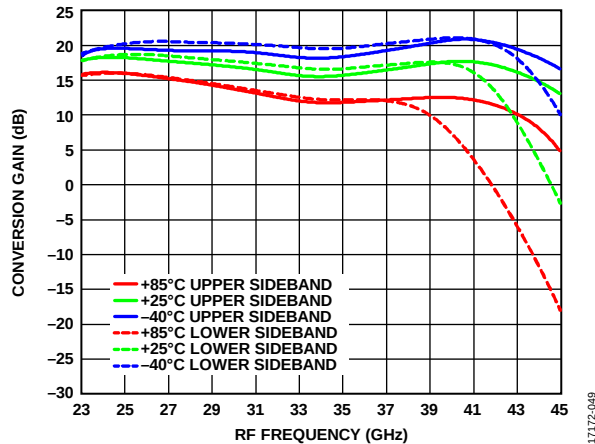


Figure 47. Conversion Gain vs. RF Frequency at Maximum Gain for Various Temperatures, $f_{IF} = 3.5$ GHz (Upper Sideband and Lower Sideband)

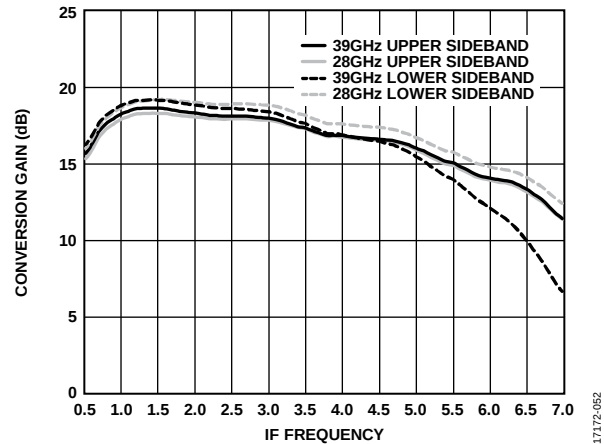


Figure 50. Conversion Gain vs. IF Frequency (f_{IF}) at Maximum Gain, $f_{RF} = 28$ GHz and 39 GHz (Upper Sideband and Lower Sideband)

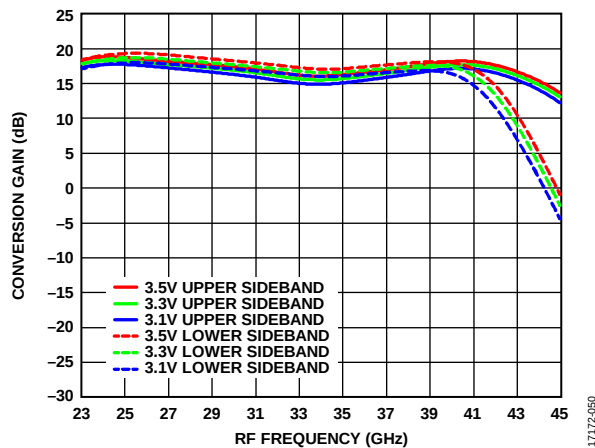


Figure 48. Conversion Gain vs. RF Frequency at Maximum Gain for Various Supply Voltages, $f_{IF} = 3.5$ GHz (Upper Sideband and Lower Sideband)

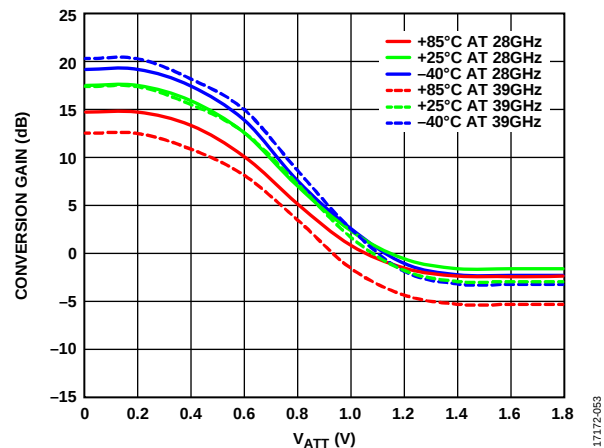


Figure 51. Conversion Gain vs. V_{ATT} at Various RF Frequencies (f_{RF}), $f_{IF} = 3.5$ GHz, $f_{RF} = 28$ GHz and 39 GHz (Upper Sideband)

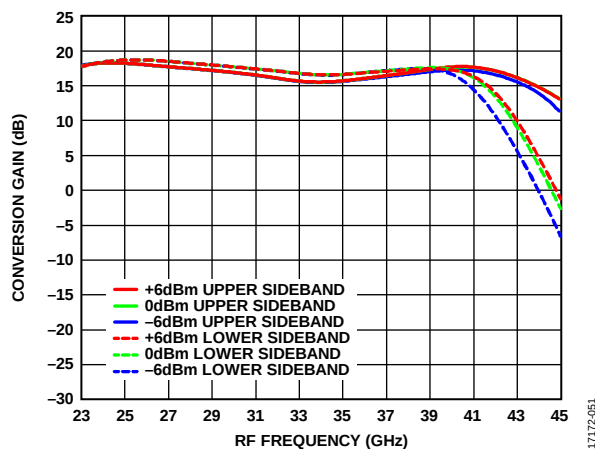


Figure 49. Conversion Gain vs. RF Frequency at Maximum Gain for Various LO Inputs, $f_{IF} = 3.5$ GHz (Upper Sideband and Lower Sideband)

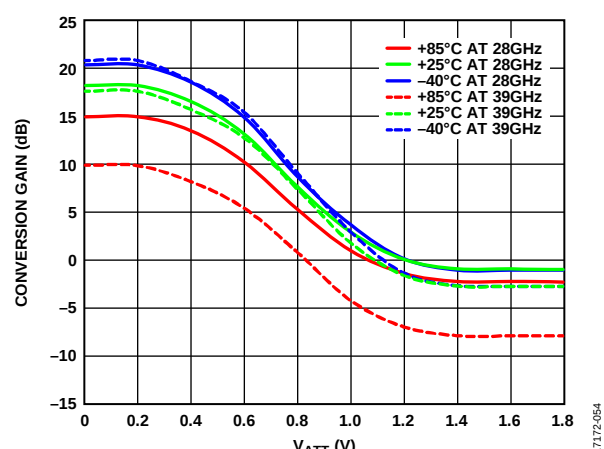


Figure 52. Conversion Gain vs. V_{ATT} at Various RF Frequencies (f_{RF}), $f_{IF} = 3.5$ GHz, $f_{RF} = 28$ GHz and 39 GHz (Lower Sideband)

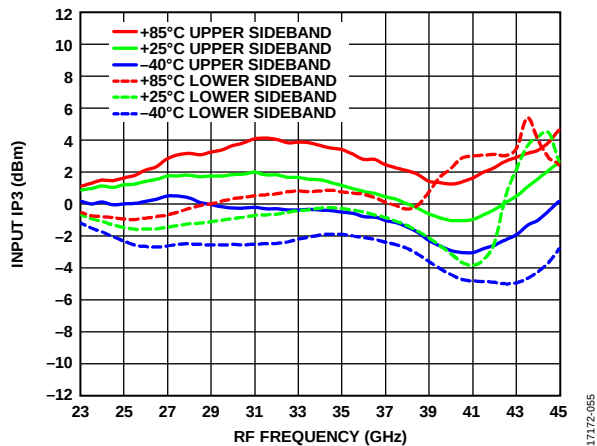


Figure 53. Input IP3 vs. RF Frequency at Maximum Gain for Various Temperatures, RF Amplitude = -30 dBm per Tone at 20 MHz Spacing, $f_{IF} = 3.5$ GHz (Upper Sideband and Lower Sideband)

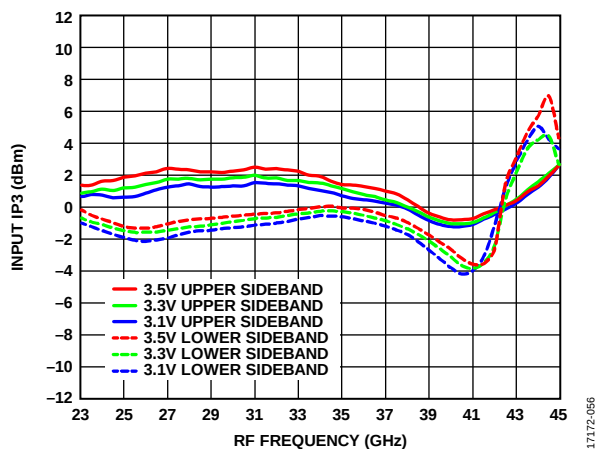


Figure 54. Input IP3 vs. RF Frequency at Maximum Gain for Various Supply Voltages, RF Amplitude = -30 dBm per Tone at 20 MHz Spacing, $f_{IF} = 3.5$ GHz (Upper Sideband and Lower Sideband)

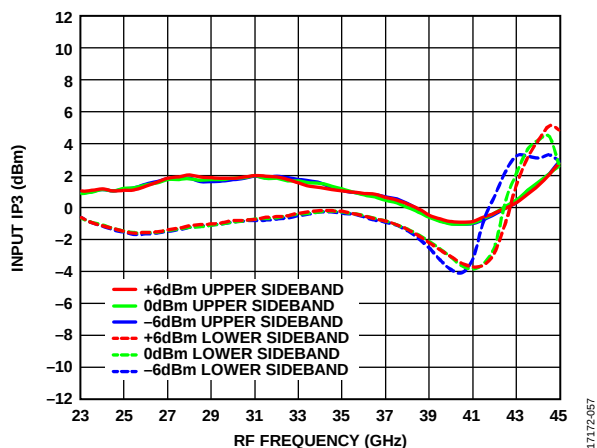


Figure 55. Input IP3 vs. RF Frequency at Maximum gain for Various LO Inputs, RF Amplitude = -30 dBm per Tone at 20 MHz Spacing, $f_{IF} = 3.5$ GHz (Upper Sideband and Lower Sideband)

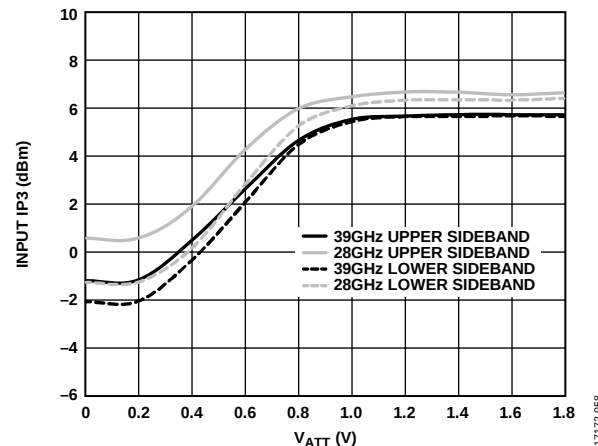


Figure 56. Input IP3 vs. V_{ATT} for Various RF Frequencies (f_{RF}), RF Amplitude = -30 dBm per Tone at 20 MHz Spacing, $f_{IF} = 3.5$ GHz at $f_{RF} = 28$ GHz and 39 GHz (Upper Sideband and Lower Sideband)

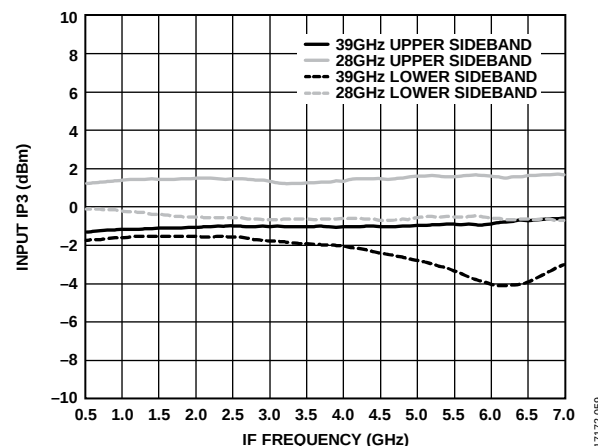


Figure 57. Input IP3 vs. IF Frequency at Maximum Gain, RF Amplitude = -30 dBm per Tone at 20 MHz Spacing at $f_{RF} = 28$ GHz and 39 GHz (Upper Sideband and Lower Sideband)

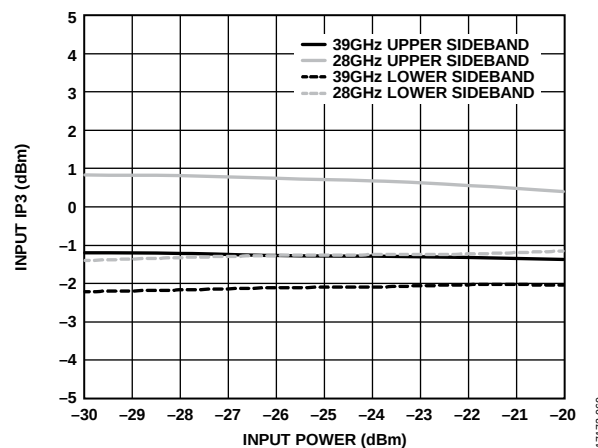


Figure 58. Input IP3 vs. Input Power for Various RF Frequencies (f_{RF}), at 20 MHz Spacing, $f_{IF} = 3.5$ GHz, $f_{RF} = 28$ GHz and 39 GHz (Upper Sideband and Lower Sideband)

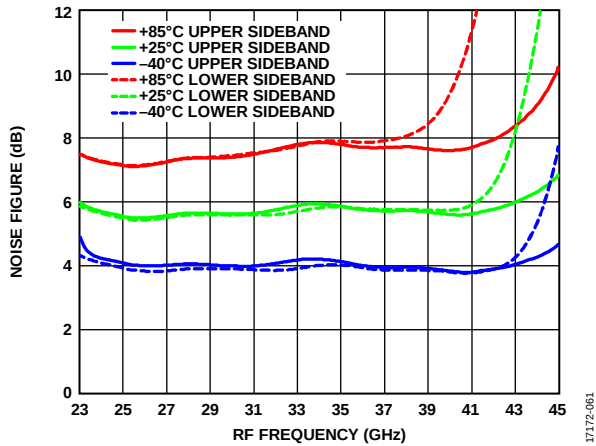


Figure 59. Noise Figure vs. RF Frequency at Maximum Gain for Various Temperatures, $f_{IF} = 3.5$ GHz (Upper Sideband and Lower Sideband)

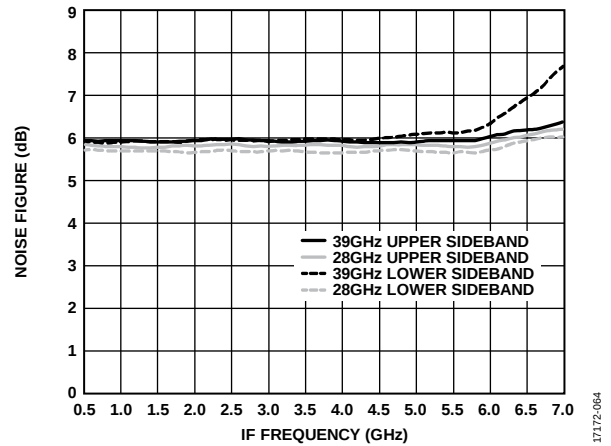


Figure 62. Noise Figure vs. IF Frequency at Maximum Gain, $f_{RF} = 28$ GHz and 39 GHz (Upper Sideband and Lower Sideband)

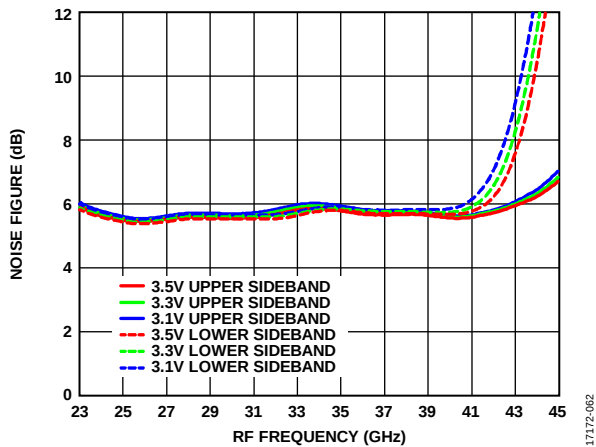


Figure 60. Noise Figure vs. RF Frequency at Maximum Gain for Various Supply Voltages, $f_{IF} = 3.5$ GHz (Upper Sideband and Lower Sideband)

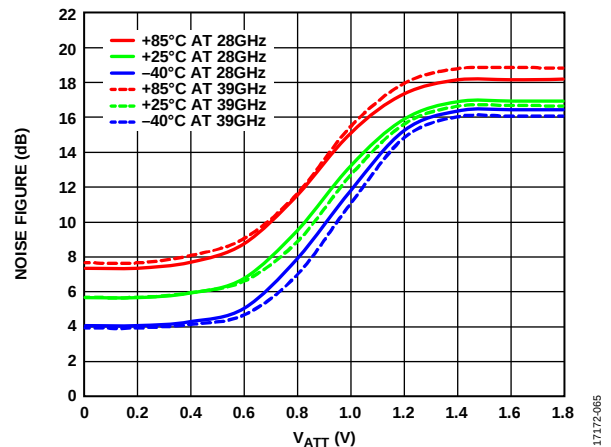


Figure 63. Noise Figure vs. V_{ATT} at Various RF Frequencies (f_{RF}), $f_{IF} = 3.5$ GHz, $f_{RF} = 28$ GHz and 39 GHz (Upper Sideband)

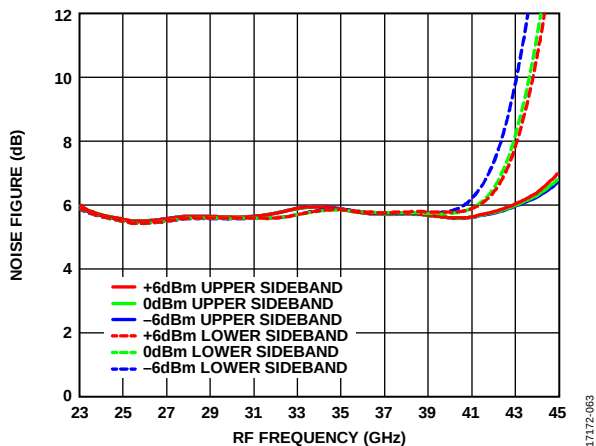


Figure 61. Noise Figure vs. RF Frequency at Maximum Gain for Various LO Inputs, $f_{IF} = 3.5$ GHz (Upper Sideband and Lower Sideband)

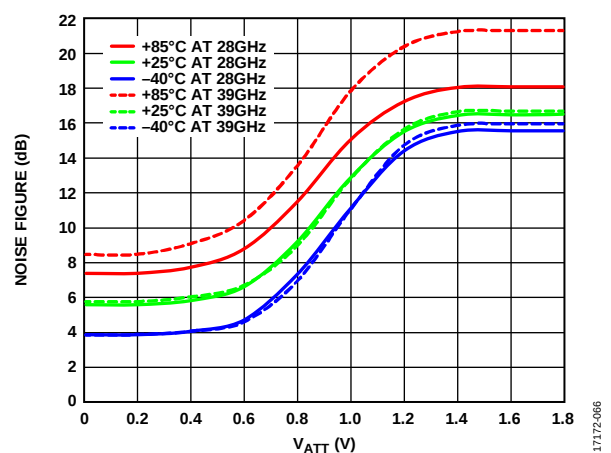


Figure 64. Noise Figure vs. V_{ATT} at Various RF Frequencies (f_{RF}), $f_{IF} = 3.5$ GHz, $f_{RF} = 28$ GHz and 39 GHz (Lower Sideband)

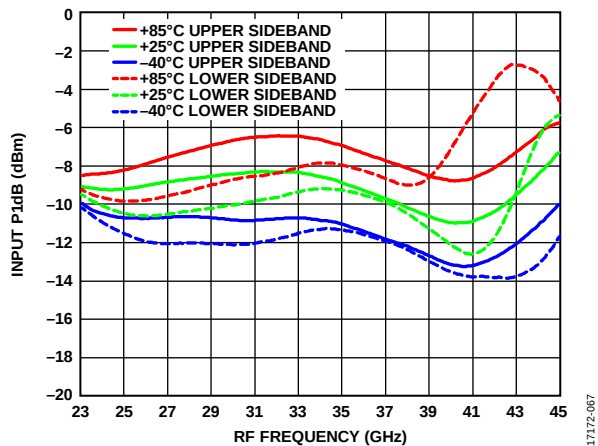


Figure 65. Input P1dB vs. RF Frequency at Maximum Gain for Various Temperatures, $f_{IF} = 3.5$ GHz (Upper Sideband and Lower Sideband)

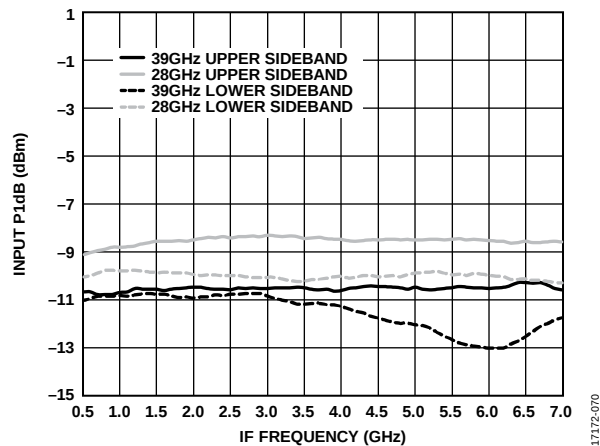


Figure 68. Input P1dB vs. IF Frequency at Maximum Gain, $f_{RF} = 28$ GHz and 39 GHz (Upper Sideband and Lower Sideband)

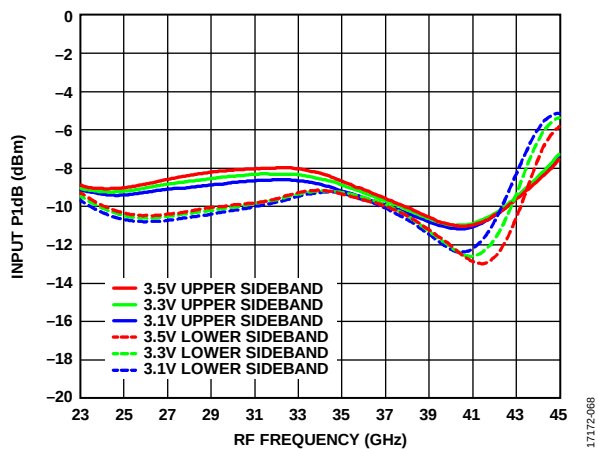


Figure 66. Input P1dB vs. RF Frequency at Maximum Gain for Various Supply Voltages, $f_{IF} = 3.5$ GHz (Upper Sideband and Lower Sideband)

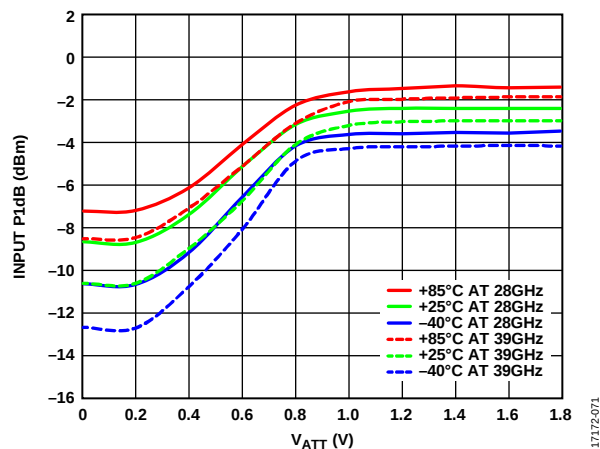


Figure 69. Input P1dB vs. V_{ATT} at Various RF Frequencies (f_{RF}), $f_{IF} = 3.5$ GHz, $f_{RF} = 28$ GHz and 39 GHz (Upper Sideband)

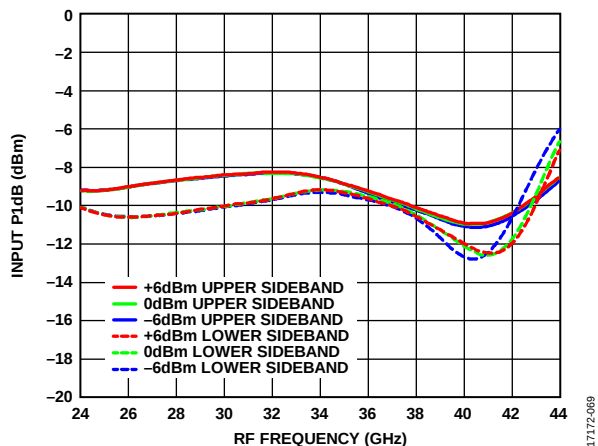


Figure 67. Input P1dB vs. RF Frequency at Maximum Gain for Various LO Inputs, $f_{IF} = 3.5$ GHz (Upper Sideband and Lower Sideband)

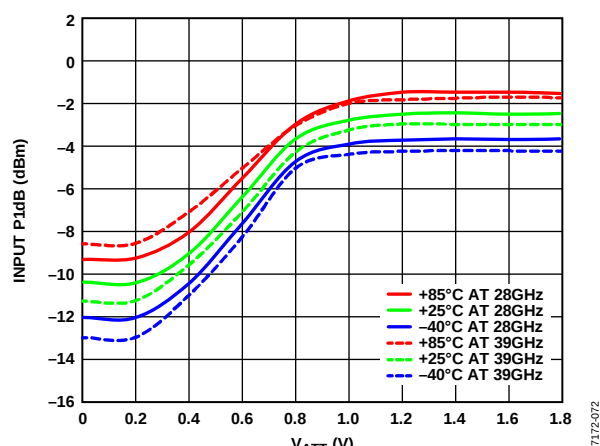


Figure 70. Input P1dB vs. V_{ATT} at Various RF Frequencies (f_{RF}), $f_{IF} = 3.5$ GHz, $f_{RF} = 28$ GHz and 39 GHz (Lower Sideband)

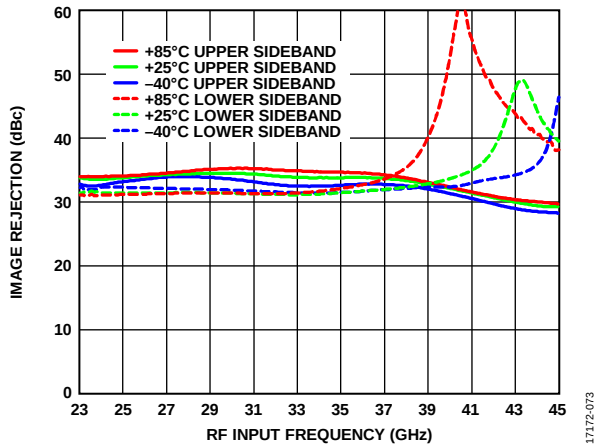


Figure 71. Image Rejection vs. RF Input Frequency at Maximum Gain for Various Temperatures, $f_{IF} = 3.5$ GHz (Upper Sideband and Lower Sideband), Uncalibrated

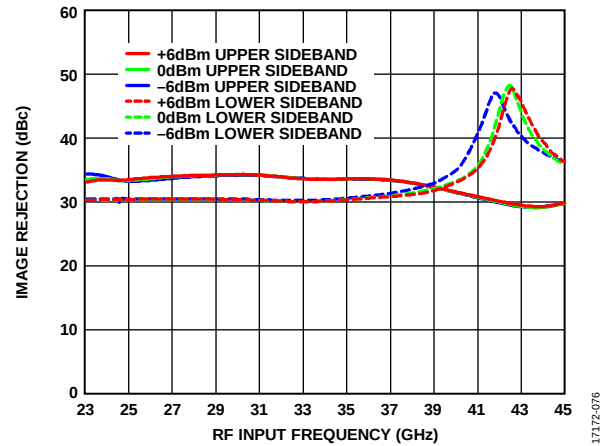


Figure 74. Image Rejection vs. RF Input Frequency at Maximum Gain for Various LO Inputs, $f_{IF} = 3.5$ GHz (Upper Sideband and Lower Sideband)

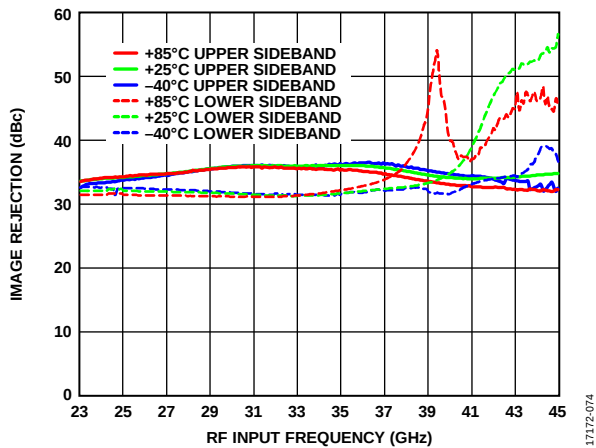


Figure 72. Image Rejection vs. RF Input Frequency at Maximum Gain for Various Temperatures, $f_{IF} = 3.5$ GHz (Upper Sideband and Lower Sideband), Calibrated

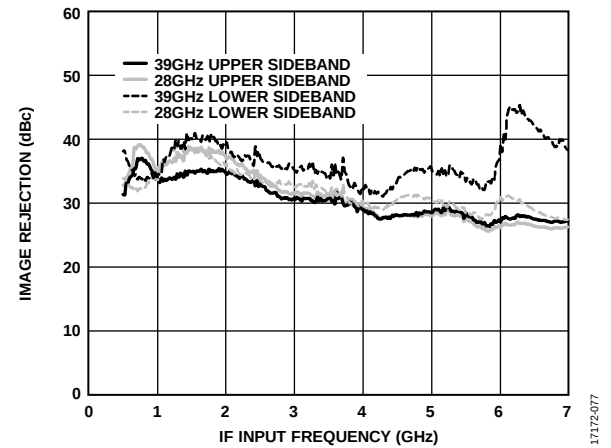


Figure 75. Image Rejection vs. IF Input Frequency at Maximum Gain, $f_{RF} = 28$ GHz and 39 GHz (Upper Sideband and Lower Sideband)

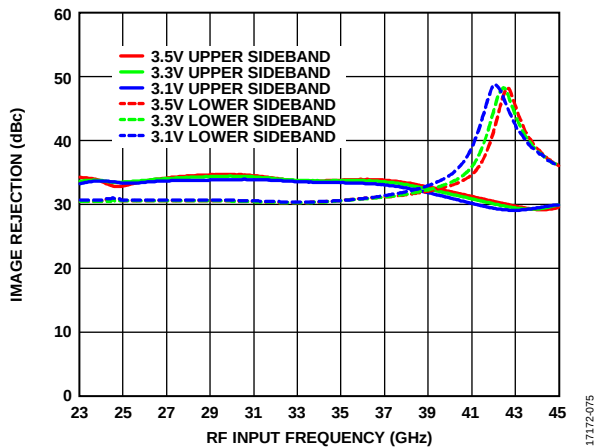


Figure 73. Image Rejection vs. RF Input Frequency at Maximum Gain for Various Supply Voltages, $f_{IF} = 3.5$ GHz (Upper Sideband and Lower Sideband)

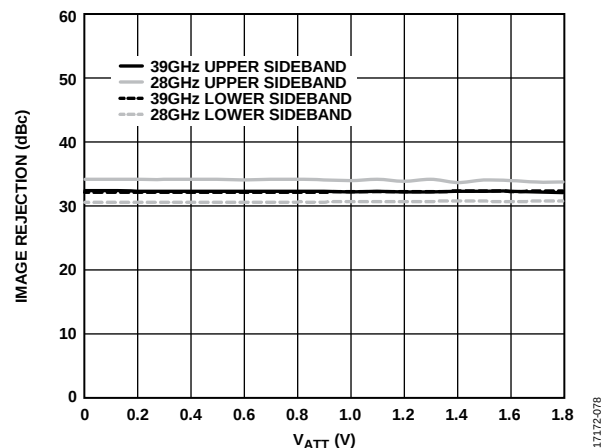


Figure 76. Image Rejection vs. V_{ATT} at Various RF Frequencies (f_{RF}), $f_{IF} = 3.5$ GHz, $f_{RF} = 28$ GHz and 39 GHz (Upper Sideband and Lower Sideband)

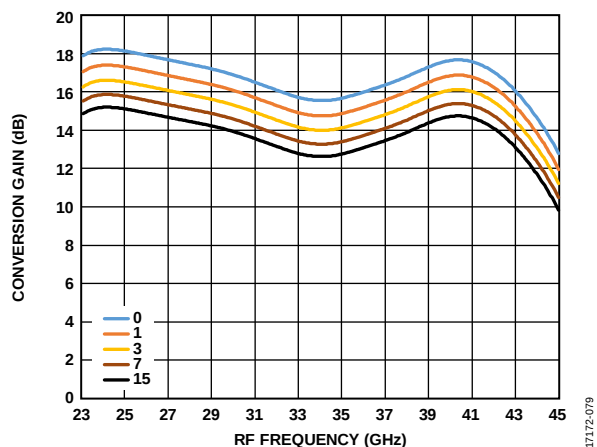


Figure 77. Conversion Gain vs. RF Frequency at Different IF_AMP_COARSE_GAIN_x Settings, $f_{IF} = 3.5$ GHz (Upper Sideband); Settings for Register 0x08, Bits[11:8] and Register 0x09, Bits[15:12] Are the Same

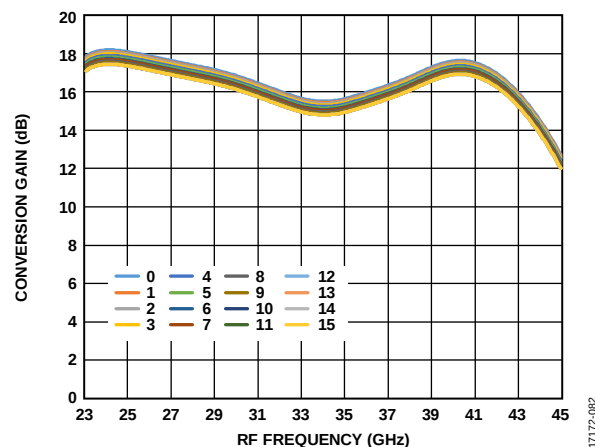


Figure 80. Conversion Gain vs. RF Frequency at Different IF_AMP_FINE_GAIN_x Settings, $f_{IF} = 3.5$ GHz (Upper Sideband); Register 0x08, Bits[7:4] and Bits[3:0] Are the Same

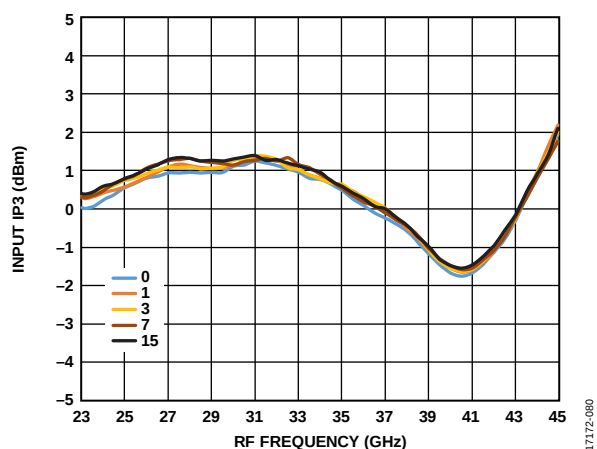


Figure 78. Input IP3 vs. RF Frequency at Different IF_AMP_COARSE_GAIN_x Settings, $f_{IF} = 3.5$ GHz (Upper Sideband); Settings for Register 0x08, Bits[11:8] and Register 0x09, Bits[15:12] Are the Same

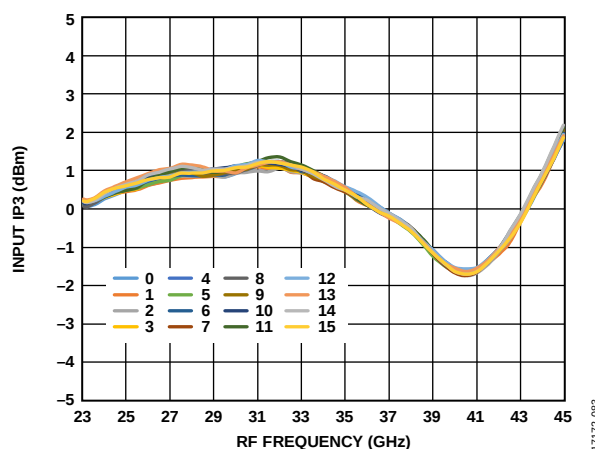


Figure 81. Input IP3 vs. RF Frequency at Different IF_AMP_FINE_GAIN_x Settings, $f_{IF} = 3.5$ GHz (Upper Sideband); Settings for Register 0x08, Bits[7:4] and Bits[3:0] Are the Same

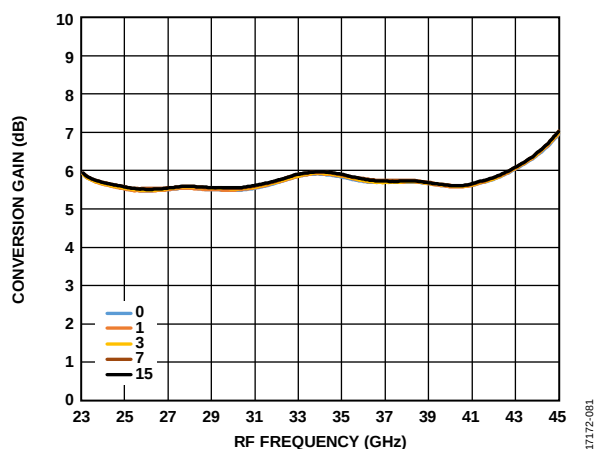


Figure 79. Conversion Gain vs. RF Frequency at Different IF_AMP_COARSE_GAIN_x Settings, $f_{IF} = 3.5$ GHz (Upper Sideband); Settings for Register 0x08, Bits[11:8] and Register 0x09, Bits[15:12] Are the Same

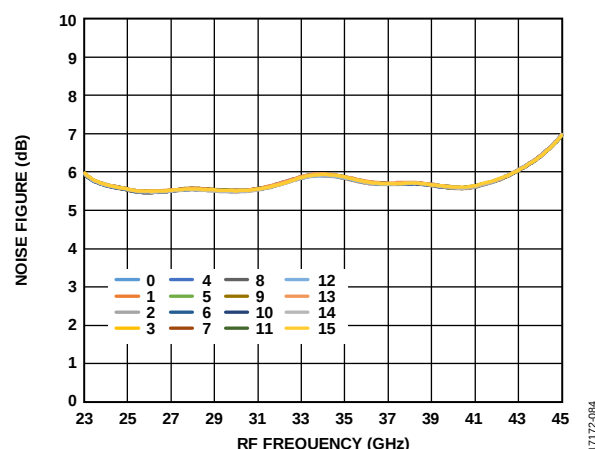


Figure 82. Noise Figure vs. RF Frequency at Different IF_AMP_FINE_GAIN_x Settings, $f_{IF} = 3.5$ GHz (Upper Sideband); Settings for Register 0x08, Bits[7:4] and Bits[3:0] Are the Same

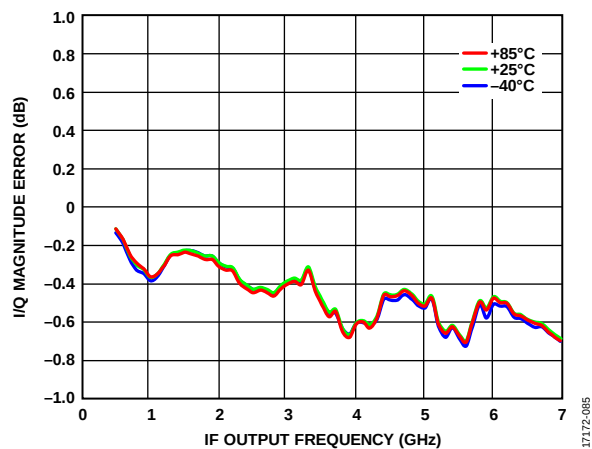


Figure 83. I/Q Magnitude Error vs. IF Output Frequency, Referenced to IF_I Output, $f_{RF} = 28$ GHz, for Various Temperatures, at Maximum Gain

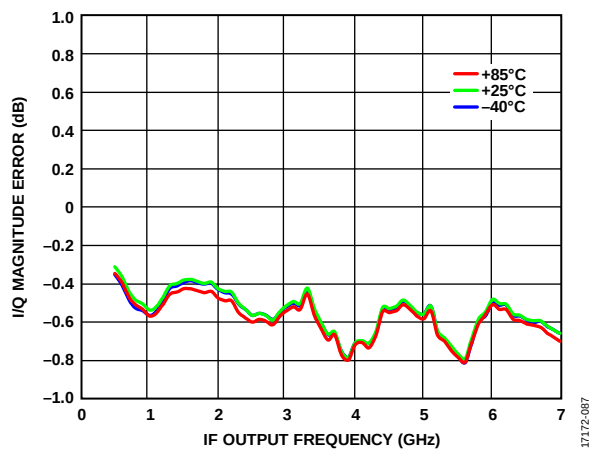


Figure 85. I/Q Magnitude Error vs. IF Output Frequency, Referenced to IF_I Output, $f_{RF} = 39$ GHz, for Various Temperatures, at Maximum Gain

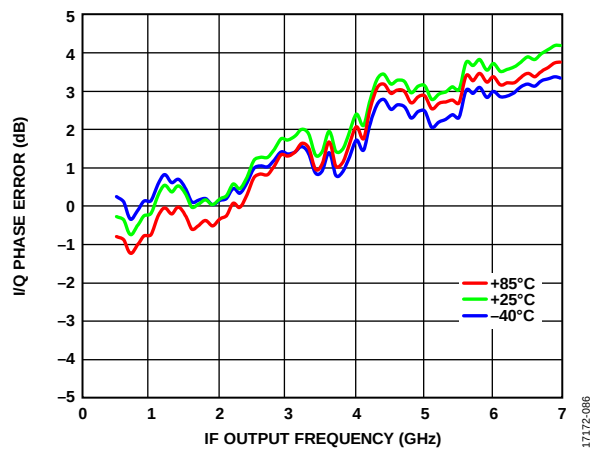


Figure 84. I/Q Phase Error vs. IF Output Frequency, Referenced to IF_I Output, $f_{RF} = 28$ GHz, for Various Temperatures, at Maximum Gain

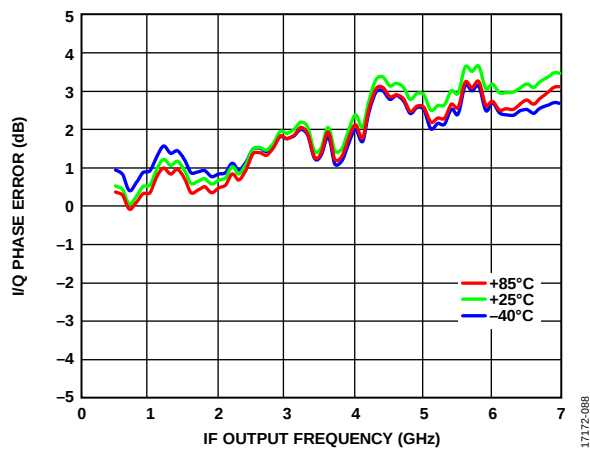


Figure 86. I/Q Phase Error vs. IF Output Frequency, Referenced to IF_I Output, $f_{RF} = 39$ GHz, for Various Temperatures, at Maximum Gain

OUTPUT DETECTOR PERFORMANCE

RF amplitude = -30 dBm, measurements performed with a 0 mV dc bias. VCC_MIXER = VCC_QUAD = VCC_BG = VCC_LNA = VCC_VGA = VCC_IF_BB = 3.3 V, DVDD = VCC_VVA = 1.8 V, Register 0x0B is set to 0x727C, Register 0x03, Bit 6 = 0, Register 0x03, Bits[13:12] set to 11, and T_A = 25°C, unless otherwise noted.

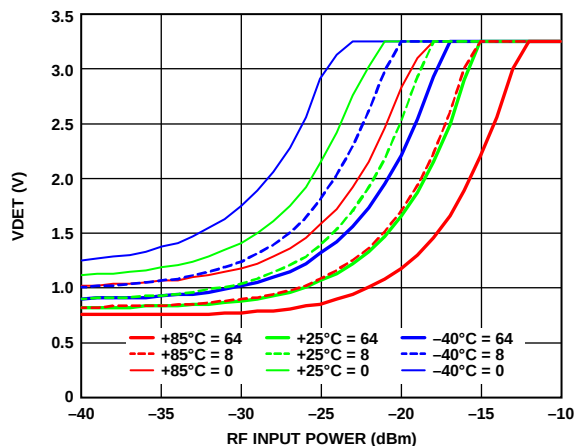


Figure 87. VDET vs. RF Input Power, $f_{RF} = 28$ GHz for Various Temperatures and DET_PROG Settings

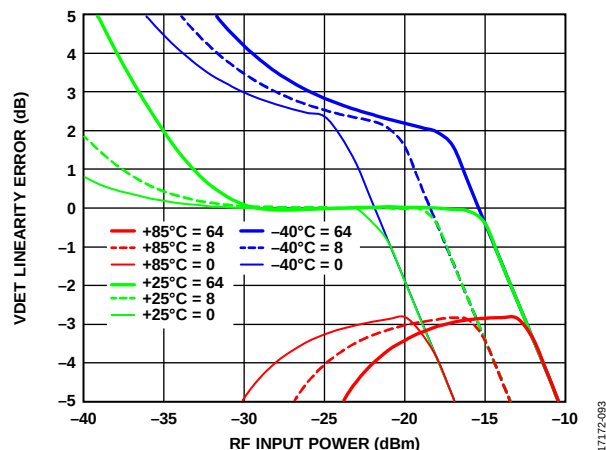


Figure 90. VDET Linearity Error vs. RF Input Power, $f_{RF} = 28$ GHz for Various Temperatures and DET_PROG Settings

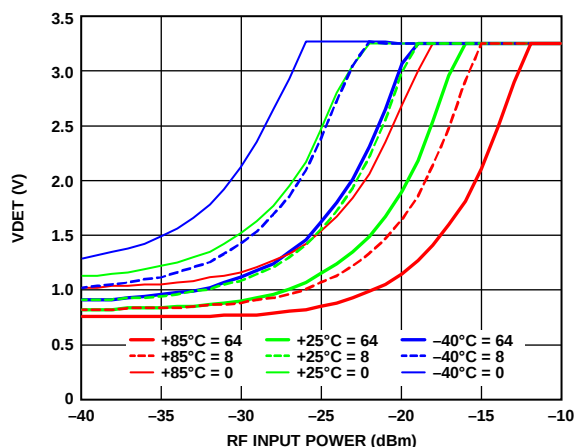


Figure 88. VDET vs. RF Input Power, $f_{RF} = 39$ GHz for Various Temperatures and DET_PROG Settings

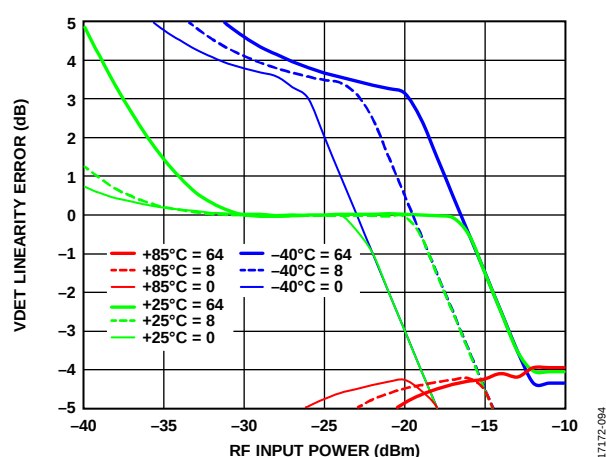


Figure 91. VDET Linearity Error vs. RF Input Power, $f_{RF} = 39$ GHz for Various Temperatures and DET_PROG Settings

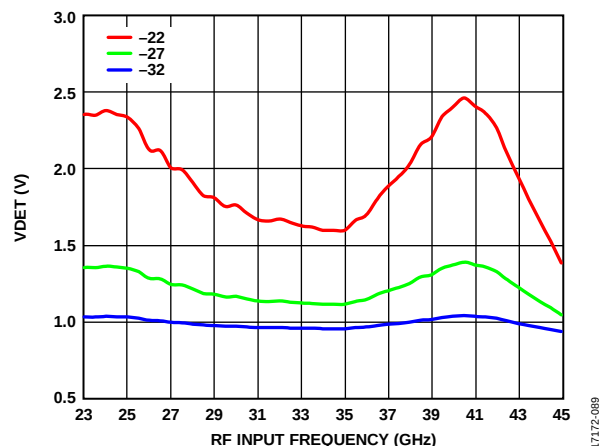


Figure 89. VDET vs. RF Input Frequency at Various Input Power Levels, DET_PROG = 8

RETURN LOSS

RF amplitude = -30 dBm, measurements performed with a 0 mV dc bias. VCC_MIXER = VCC_QUAD = VCC_BG = VCC_LNA = VCC_VGA = VCC_IF_BB = 3.3 V, DVDD = VCC_VVA = 1.8 V, Register 0x0B is set to 0x727C, Register 0x03, Bits[13:12] are set to 11, and T_A = 25°C, unless otherwise noted.

Measurements in IF mode performed with a 90° hybrid, Register 0x03, Bit 11 = 0, Register 0x03, Bit 8 = 1, unless otherwise noted.

Measurements in I/Q mode are measured as a composite of the I and Q channel performed, V_{CM} = 1.15 V, Register 0x03, Bit 11 = 1, and Register 0x03, Bit 8 = 0, unless otherwise noted.

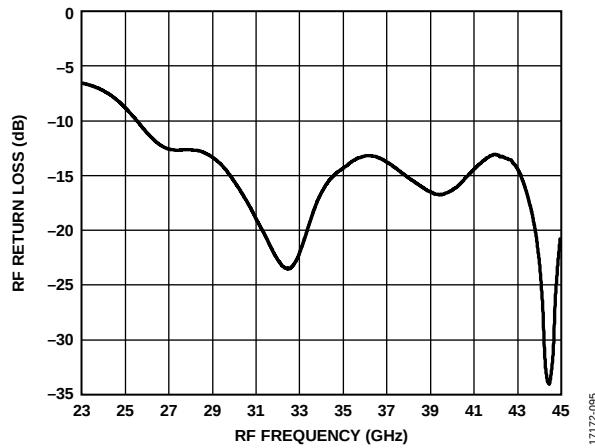


Figure 92. RF Input Return Loss vs. RF Frequency

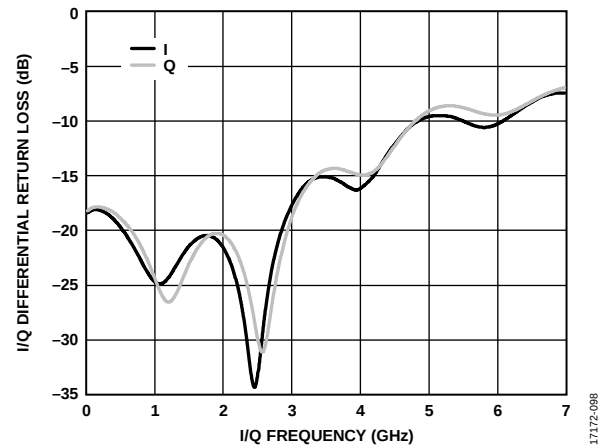


Figure 95. I/Q Differential Return Loss vs. I/Q Frequency (Taken Without Hybrids or Baluns)

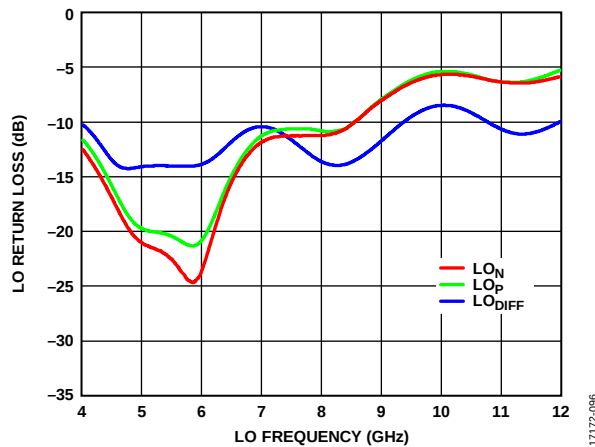


Figure 93. LO Return Loss vs. LO Frequency

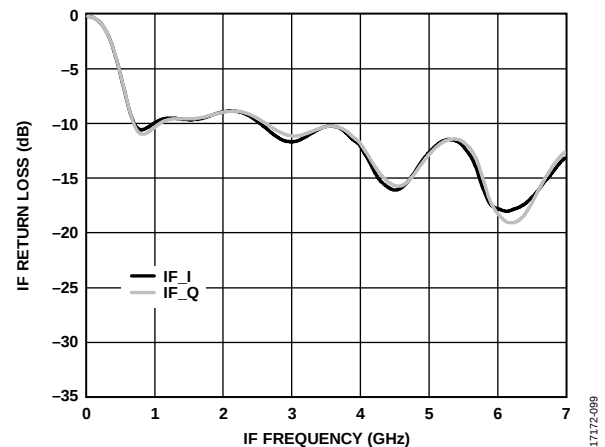


Figure 96. IF Return Loss vs. IF Frequency (Taken Without Hybrid)

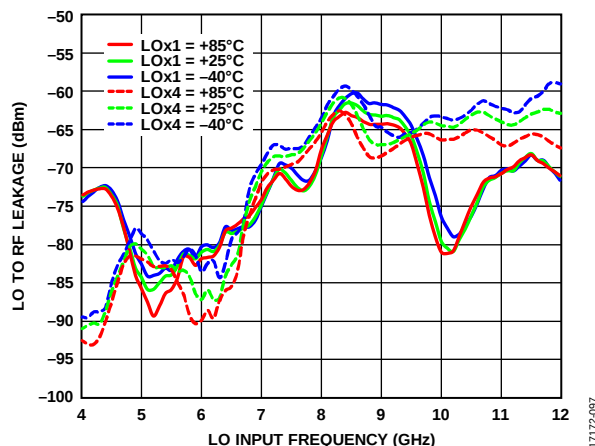


Figure 94. LO to RF Leakage vs. LO Input Frequency for Various Temperatures at Different Gain Settings

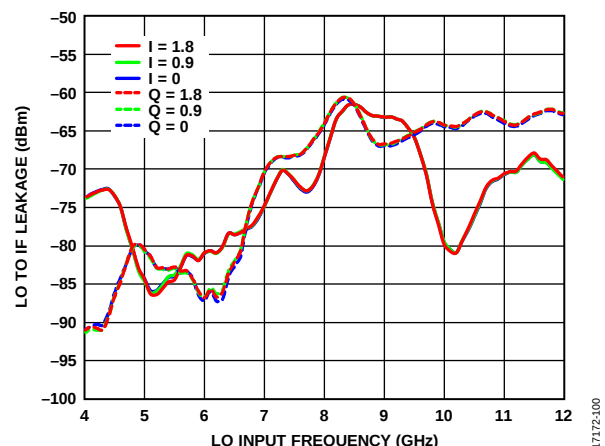


Figure 97. LO to IF Leakage vs. LO Input Frequency at Different VCTRL Settings

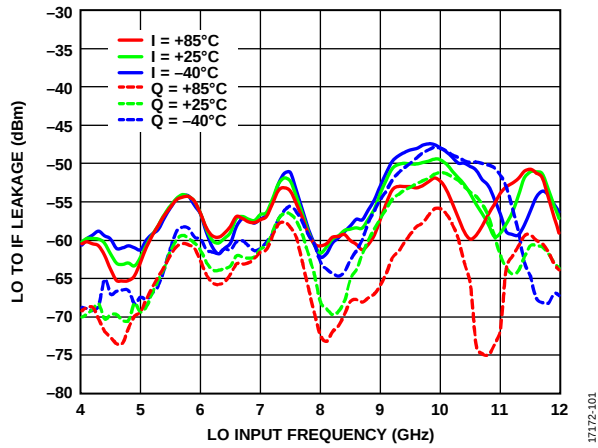


Figure 98. LO to IF Leakage vs. LO Input Frequency at Various Temperatures

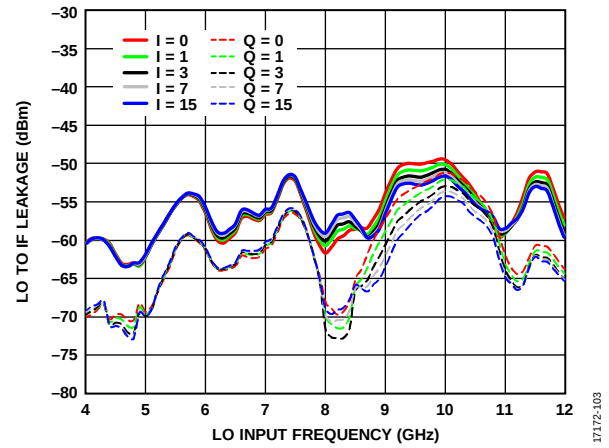


Figure 100. LO to IF Leakage, vs. LO Input Frequency at Different IF Amplifier Gain Settings (Taken Without Hybrid)

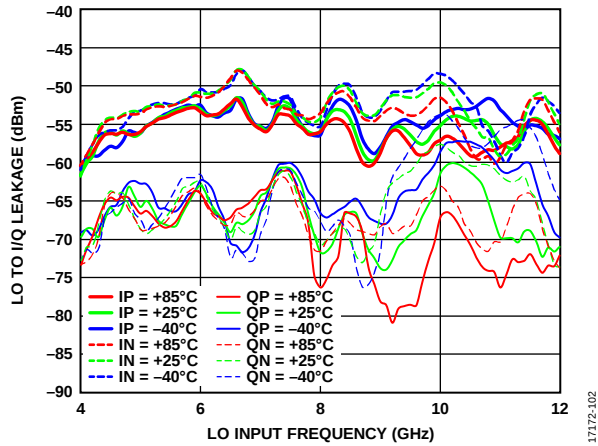


Figure 99. LO to I/Q Leakage vs. LO Input Frequency at Various Temperatures (Taken Without Hybrid)

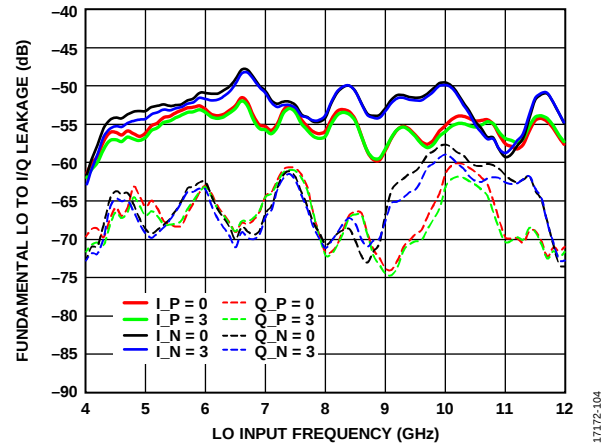


Figure 101. Fundamental LO to I/Q Leakage vs. LO Input Frequency at Different Baseband Amplifier Gain Settings

M × N SPURIOUS PERFORMANCE

Mixer spurious products are measured in dBc from the IF output power level. Spurious values are measured using the following equation:

$$|(M \times RF) + (N \times LO)|$$

N/A means not applicable. Blank cells in the spurious performance tables indicate that the frequency is above 50 GHz and is not measured.

The LO frequencies are referred from the frequencies applied to the LO_x pin of the ADMV1014. RF amplitude = -30 dBm, measurements performed with a 0 mV dc bias. VCC_MIXER = VCC_QUAD = VCC_BG = VCC_LNA = VCC_VGA = VCC_IF_BB = 3.3 V, DVDD = VCC_VVA = 1.8 V, Register 0x0B is set to 0x727C, Register 0x03, Bits[13:12] are set to 11, and T_A = 25°C, unless otherwise noted.

Measurements in IF mode performed with Register 0x03, Bit 11 = 0 and Register 0x03, Bit 8 = 1, unless otherwise noted.

The measurements in I/Q mode are as follows: V_{CM} = 1.15 V, Register 0x03, Bit 11 = 1, and Register 0x03, Bit 8 = 0, unless otherwise noted.

I/Q Mode

Measurements are made on the I_P port. Data is taken without any hybrids or baluns.

BB frequency (f_{BB}) = 100 MHz, LO = 6.975 GHz at 0 dBm, and f_{RF} = 28 GHz at -30 dBm.

		N × LO								
		0	1	2	3	4	5	6	7	8
M × RF	−2		85	87	87	82	86	103	96	59
	−1	61	90	54	46	0	45	52	106	82
	0	N/A	43	55	65	48	76	78	81	
	+1	61	91	80	82					

f_{BB} = 100 MHz, LO = 9.725 GHz at 0 dBm, and f_{RF} = 39 GHz at -30 dBm.

		N × LO								
		0	1	2	3	4	5	6	7	8
M × RF	−2				85	88	87	92	87	60
	−1	63	92	56	47	0	51	61	85	84
	0	N/A	42	48	67	51	85			
	+1	42	48							

IF Mode

Measurements are made on the IF_I port. Data is taken without any 90° hybrid.

IF frequency (f_{IF}) = 3.5 GHz, LO = 6.125 GHz at 0 dBm, and f_{RF} = 28 GHz at -30 dBm.

		N × LO								
		0	1	2	3	4	5	6	7	8
M × RF	−2		81	93	85	93	93	99	96	57
	−1	66	94	89	63	0	44	46	92	78
	0	N/A	45	43	65	54	71	64	80	58
	+1	66	84	84	81					

f_{IF} = 3.5 GHz, LO = 8.875 GHz at 0 dBm, and f_{RF} = 39 GHz at -30 dBm.

		N × LO								
		0	1	2	3	4	5	6	7	8
M × RF	−2					84	92	91	93	59
	−1	62	93	81	71	0	39	91	92	89
	0	N/A	47	68	75	50	75			
	+1	62	89							

f_{IF} = 3.5 GHz, LO = 7.875 GHz at 0 dBm, and f_{RF} = 28 GHz at -30 dBm.

		N × LO								
		0	1	2	3	4	5	6	7	8
M × RF	−2		90	86	83	95	94	83	89	58
	−1	70	93	70	41	0	65	90	89	83
	0	N/A	47	62	66	49	74	86		
	+1	70	90	88						

f_{IF} = 3.5 GHz, LO = 10.5 GHz at 0 dBm, and f_{RF} = 39 GHz at -30 dBm.

		N × LO								
		0	1	2	3	4	5	6	7	8
M × RF	−2				85	87	94	94	90	58
	−1	61	91	81	35	0	87	84	84	82
	0	N/A	39	51	62	53				
	+1	61	89							

THEORY OF OPERATION

The ADMV1014 is a wideband microwave downconverter optimized for microwave radio designs operating in the 24 GHz to 44 GHz frequency range. See Figure 1 for a functional block diagram of the device. The ADMV1014 digital settings are controlled via the SPI. The ADMV1014 has two modes of operation:

- Baseband quadrature demodulation (I/Q mode)
- Image reject I/Q downconversion (IF mode)

START-UP SEQUENCE

The ADMV1014 SPI settings require its default settings to be changed during startup for optimum performance.

Set Register 0x0B to 0x727C after every power-up or reset. Set Register 0x03, Bits[13:12] to 11 after every power-up or reset.

BASEBAND QUADRATURE DEMODULATION (I/Q MODE)

In I/Q mode, the output impedance of the baseband I/Q ports is 100 Ω differential. These outputs are designed to be loaded to a dc-coupled, differential, 100 Ω load. I_P and I_N are the differential baseband I outputs. Q_P and Q_N are the differential baseband Q outputs.

To set the ADMV1014 in I/Q mode, set BB_AMP_PD (Register 0x03, Bit 8) to 0 and set IF_AMP_PD (Register 0x03, Bit 11) to 1.

The baseband I/Q ports are designed to operate from dc to 6.0 GHz at each I and Q channel.

The BB output V_{CM} can be changed from 1.05 V to 1.85 V. To change the V_{CM} , set BB_SWITCH_HIGH_LOW_COMMON (Register 0x0A, Bit 0) to be the opposite of Register 0x0A, Bit 6. Also, set the MIXER_VGATE bit field (Register 0x07, Bits[15:9]) and the BB_AMP_REF_GEN bit field (Register 0x0A, Bits[6:3]) based on Table 6.

Table 6 provides the correct setting for these bit fields vs. the required common-mode voltage.

The V_{CM} can be further adjusted on each I or Q channel by ± 15 mV by setting the BB_AMP_OFFSET_I bit field (Register 0x09, Bits[4:0]) and the BB_AMP_OFFSET_Q bit field (Register 0x09, Bits[9:5]) for each V_{CM} setting shown in Table 6.

The most significant bit (MSB) for each bit field is the sign bit. When the MSB is 1, the values of the four lower bits are positive. When the MSB is 0, the values of the four lower bits are negative. These bits also offer input IP2 and common-mode rejection optimization.

The BB I/Q section of the ADMV1014 also features a baseband amplifier with a digital attenuator that is controlled by setting the BB_AMP_GAIN_CTRL bit field (Register 0x0A, Bits[2:1]). Figure 44, Figure 45, and Figure 46 show the performance of the baseband digital attenuator.

The Baseband Quadrature Demodulation to Very Low Frequencies section shows the baseband performance to very low demodulation frequencies.

Table 6. Common-Mode Voltage Settings

V_{CM} (V)	MIXER_VGATE (Register 0x07, Bits[15:9])	BB_AMP_REF_GEN (Register 0x0A, Bits[6:3])	BB_SWITCH_HIGH_LOW_COMMON_MODE (Register 0x0A, Bit 0)
1.05	1101010	0000	1
1.10	1101011	0001	1
1.15	1101100	0010	1
1.20	1101110	0011	1
1.25	1101111	0100	1
1.30	1110000	0101	1
1.35	1110001	0110	1
1.40	1110010	0111	1
1.50	1110101	1000	0
1.55	1110110	1001	0
1.60	1110111	1010	0
1.65	1111000	1011	0
1.70	1111010	1100	0
1.75	1111011	1101	0
1.80	0101100	1110	0
1.85	0101101	1111	0

IMAGE REJECTION DOWNCONVERSION

The ADMV1014 features the ability to downconvert to a real IF output anywhere from 800 MHz to 6000 MHz, while suppressing the unwanted image sideband by typically better than 30 dBc. The IF outputs are quadrature to each other, 50 Ω single-ended, and are internally ac coupled. IF_I and IF_Q are the quadrature IF outputs. An external 90° hybrid is required to select the appropriate sideband.

To configure the ADMV1014 in IF mode, set BB_AMP_PD (Register 0x03, Bit 8) to 1 and set IF_AMP_PD (Register 0x03, Bit 10) to 0

Each IF output features an amplifier with a digital attenuator. The digital attenuator can be adjusted using fine or coarse steps. The coarse steps for the IF_I can be adjusted using the IF_AMP_COARSE_GAIN_I bit field (Register 0x08, Bits[11:8]). The coarse steps for the IF_Q can be adjusted using the IF_AMP_COARSE_GAIN_Q bit field (Register 0x09, Bits[15:12]). Each coarse gain bit field has five settings. The fine steps for IF_I can be adjusted using the IF_AMP_FINE_GAIN_I bit field (Register 0x08, Bits[3:0]). The fine steps for the IF_Q can be adjusted using the IF_AMP_FINE_GAIN_Q bit field (Register 0x08, Bits[7:4]). Figure 77 to Figure 82 show the performance of these four bit fields.

DETECTOR

The ADMV1014 features a square law detector that produces a voltage linearly, according to the square of the RF voltage output from the low noise amplifier. The detector can be enabled by setting the DET_EN bit (Register 0x03, Bit 6) to 0. The detector can be turned off by setting this bit to 1. The detector linear range can be adjusted by setting the DET_PROG bit field (Register 0x07, Bits[6:0]). These ranges are specified based on the input power into the detector coming from the output of the low noise amplifier. Each DET_PROG setting offers an approximate 20 dB of ± 1 dB dynamic range based on a two-point linear regression from an ideal line for one temperature at each DET_PROG setting. See Figure 89 to Figure 91 for more performance information of the detector.

LO INPUT PATH

The LO input path operates from 5.4 GHz to 10.25 GHz with an LO amplitude range of -6 dBm to +6 dBm. The LO has an internal quadrupler ($\times 4$) and a programmable band-pass filter. The LO band-pass filter is programmable using QUAD_FILTERS (Register 0x09 Bits[3:0]). See the Performance at Different Quad Filter Settings section for more information on the QUAD_FILTERS settings.

The LO path can operate either differentially or single-ended (SE). LOIP and LOIN are the inputs to the LO path. The LO

path can switch from differential to single-ended operation by setting the QUAD_SE_MODE bits (Register 0x04, Bits[9:6]). See the Performance Between Differential vs. Single-Ended LO Input section for more information.

Figure 102 shows a block diagram of the LO path.

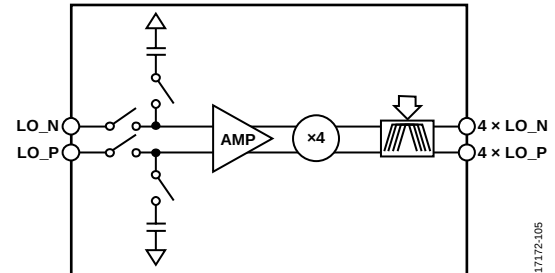


Figure 102. LO Path Block Diagram

Enable the quadrupler by setting the QUAD_IBIAS_PD bit (Register 0x03, Bit 7) to 0 and the QUAD_BG_PD bit (Register 0x03, Bit 9) to 0. To power down the quadrupler, set both of these bits to 1.

An unwanted image can be downconverted from the quadrature error in generating the quadrature LO signals. Deviation from ideal quadrature (that is, total image rejection and no image tone is downconverted) on these signals limits the amount of achievable image rejection.

The ADMV1014 offers about 25° of quadrature phase adjustment in the LO path quadrature signals. Make these adjustments through the LOAMP_PH_ADJ_I_FINE bits (Register 0x05, Bits[15:9]) and the LOAMP_PH_ADJ_Q_FINE (Register 0x05, Bits[8:2]) bits. These bits reject the unwanted sideband signal. In IF mode amplitude adjustments can be made to the complex outputs via IF_AMP_FINE_GAIN_Q (Register 0x08, Bits[7:4]) and IF_AMP_FINE_GAIN_I (Register 0x08, Bits[3:0]) to further reduce the unwanted sideband.

POWER-DOWN

The SPI of the ADMV1014 allows the user to power down device circuits and reduce power consumption. There are two power-down modes: band gap power-down mode (BG_PD) and individual power-down circuits mode. The BG_PD bit (Register 0x03, Bit 5) and the QUAD_BG_PD bit (Register 0x03, Bit 9) power down the band gap circuit. The QUAD_IBIAS_PD bit (Register 0x03, Bit 7) and the IBIAS_PD bit (Register 0x03, Bit 14) power down the specific circuits.

Table 7 shows the circuits that are controlled by their related power-down bit, the typical power savings, and the latency requirement to power the circuits back up.

Table 7. Power-Down Power and Latency Requirements

Bit Name	Circuit	Typical Power Savings (mW)	Power-Up Latency (μs)	Power-Down Latency (μs)
IBIAS_PD	Receiver bias current (I_{BIAS})	1172	5	<1
QUAD_IBIAS_PD	LO path	238	4	<1
BG_PD and QUAD_BG_PD	Band gap	1423	4.5	<1
IBIAS_PD, IF_AMP_PD, QUAD_BG_PD, BB_AMP_PD, QUAD_IBIAS_PD, BG_PD	Entire chip	1435	5	<1

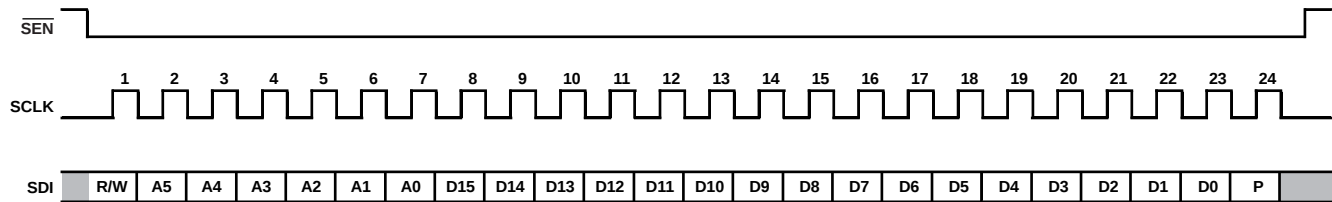


Figure 103. Write Serial Port Timing Diagram

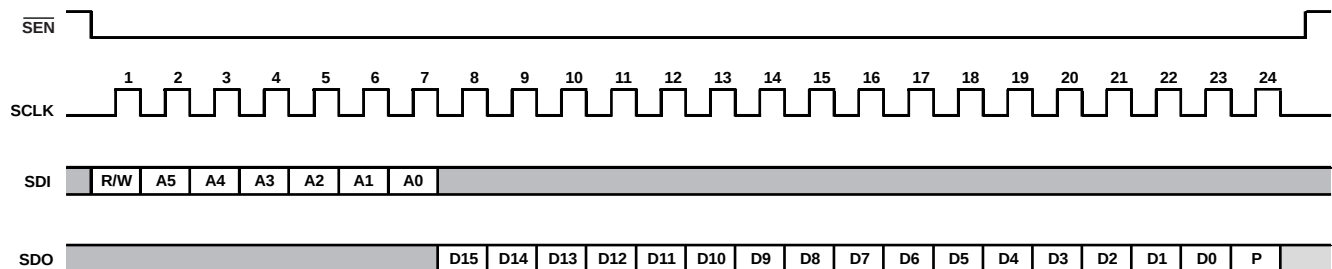


Figure 104. Read Serial Port Timing Diagram

SERIAL PORT INTERFACE (SPI)

The SPI of the ADMV1014 allows the user to configure the device for specific functions or operations via a 4-pin SPI port. This interface provides users with added flexibility and customization. The SPI consists of four control lines: SCLK, SDIN, SDO, and SEN.

The ADMV1014 protocol consists of a write/read bit followed by six register address bits, 16 data bits, and a parity bit. Both the address and data fields are organized most significant bit (MSB) first and end with the least significant bit (lower sideband). For a write, set the first bit to 0. For a read, set the first bit to 1.

The write cycle sampling must be performed on the rising edge. The 16 bits of the serial write data are shifted in, MSB to Lower

Sideband. The ADMV1014 input logic level for the write cycle supports an 1.8 V interface.

For a read cycle, up to 16 bits of serial read data are shifted out, MSB first. After the 16 bits of data shift out, the parity bit shifts out. The output logic level for a read cycle is 1.8 V.

The parity bit always follows the direction of the data. If parity is not used, the transmitting end transmits zero instead of parity. The parity is odd, which means that the total number of ones transmitted during a command, including the read/write bit, the address bit, the data bit, and the parity bit, must be odd.

Figure 103 and Figure 104 show the SPI write and read protocol, respectively.

APPLICATIONS INFORMATION

ERROR VECTOR MAGNITUDE (EVM) PERFORMANCE

Figure 105 shows the EVM vs. input power performance of the ADMV1014 in IF mode at maximum gain, upper sideband, 25°C and 0 dBm LO input power. The EVM measurement was performed using four 100 MHz, 5G-NR, 256QAM waveforms. The EVM shown is the average of the four channels. The EVM of the test equipment was not de-embedded.

Figure 106 shows the constellation diagram and EVM statistics of each of the four channels at -30 dBm input power.

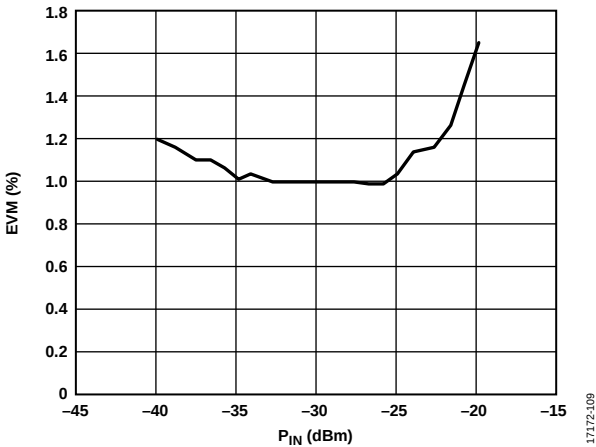


Figure 105. EVM vs. Input Power at 28 GHz, VCTRL = 0 V, T_A = 25°C, LO = 0 dBm, Upper Sideband (Low-Side LO), IF = 3.5 GHz

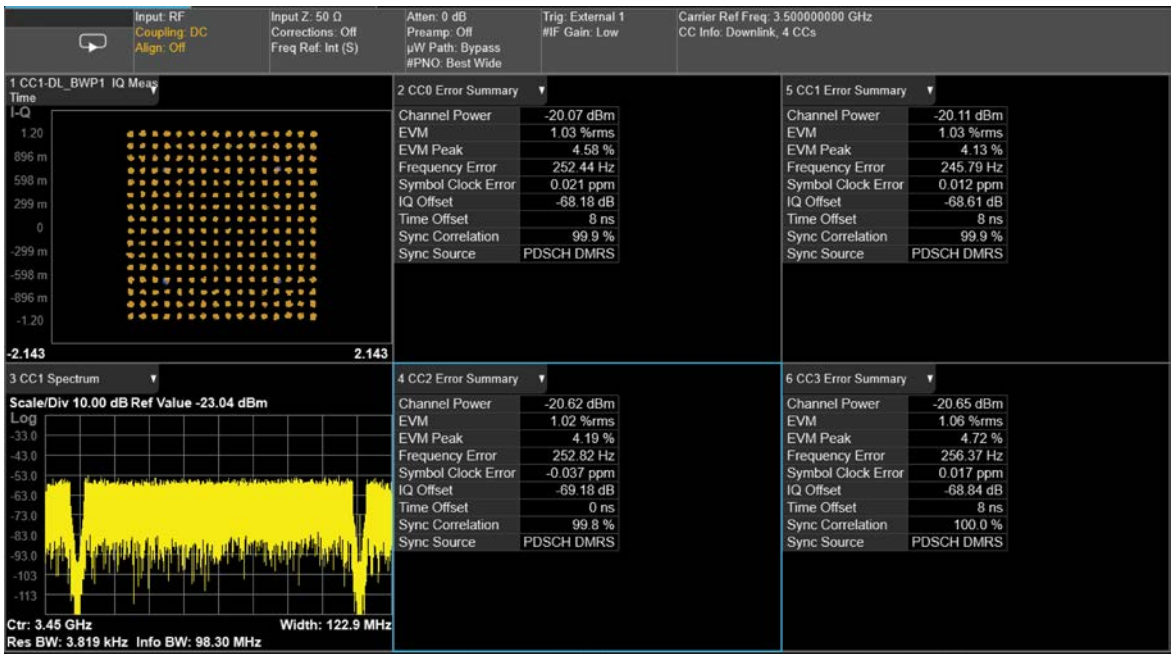


Figure 106. Constellation Diagram and EVM Statistics per Channel

BASEBAND QUADRATURE DEMODULATION TO VERY LOW FREQUENCIES

Figure 107 to Figure 111 show the I/Q mode performance at low baseband frequencies. The measurements were performed at 28 GHz, -25 dBm input power, $V_{CM} = 1.15$ V, Register 0x03, Bit 11 = 1, Register 0x03, Bit 8 = 0, 6 dBm LO input power, and $T_A = 25^\circ\text{C}$.

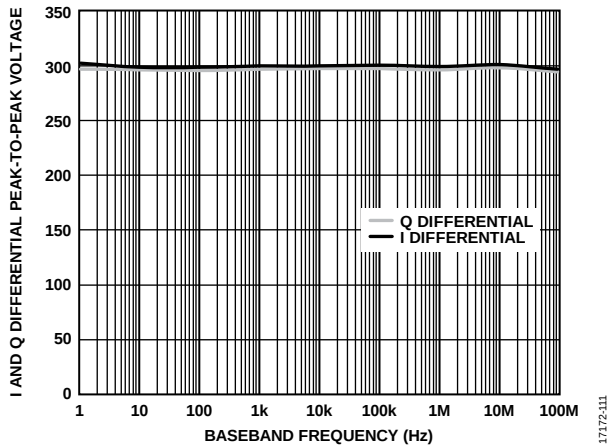


Figure 107. I and Q Differential Peak-to-Peak Voltage vs. Baseband Frequency,

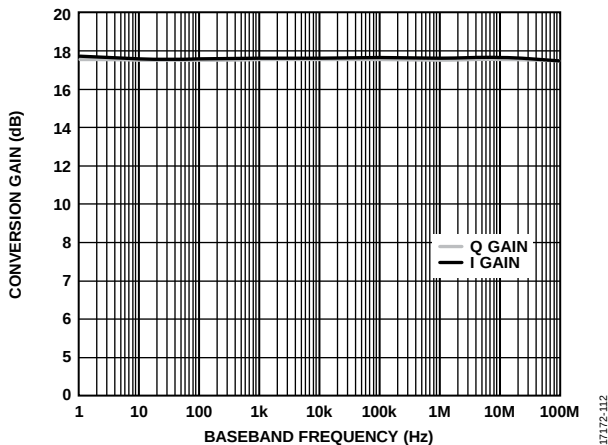


Figure 108. Conversion Gain vs. Baseband Frequency

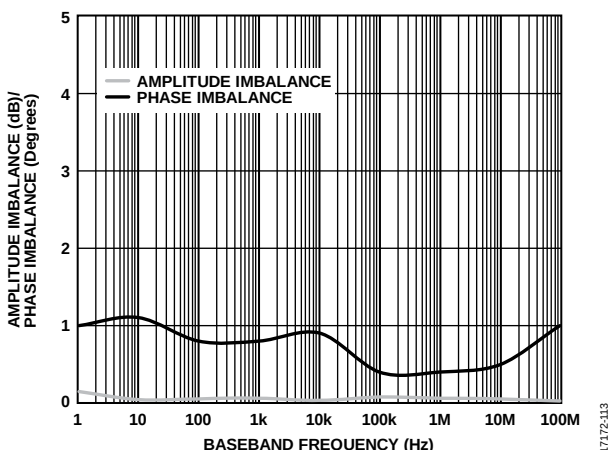


Figure 109. Amplitude Imbalance and Phase Imbalance vs. Baseband Frequency

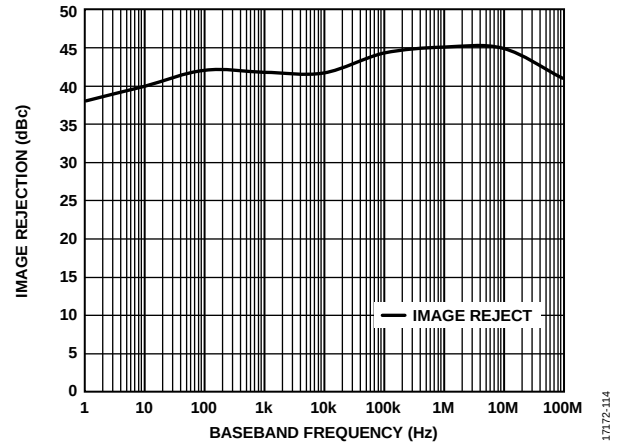


Figure 110. Image Rejection vs. Baseband Frequency

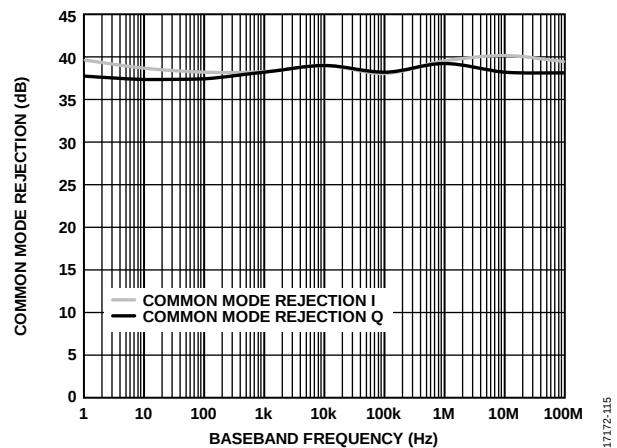


Figure 111. Common-Mode Rejection vs. Baseband Frequency

PERFORMANCE AT DIFFERENT QUAD FILTER SETTINGS

Figure 112 shows the conversion gain vs. RF frequency in IF mode at 25°C and LO input power = 6 dBm, for different QUAD_FILTERS settings. Figure 113 shows the LO to IF_I and LO to IF_Q leakage vs. LO frequency at different quad filter settings.

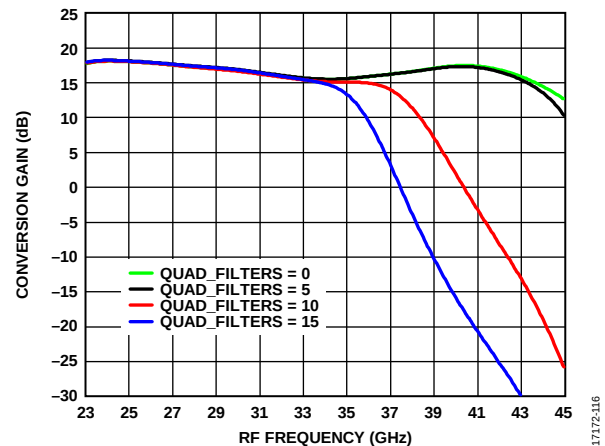


Figure 112. Conversion Gain vs. RF Frequency for Four Different QUAD_FILTERS Settings, $f_r = 3.5$ GHz (Upper Sideband)

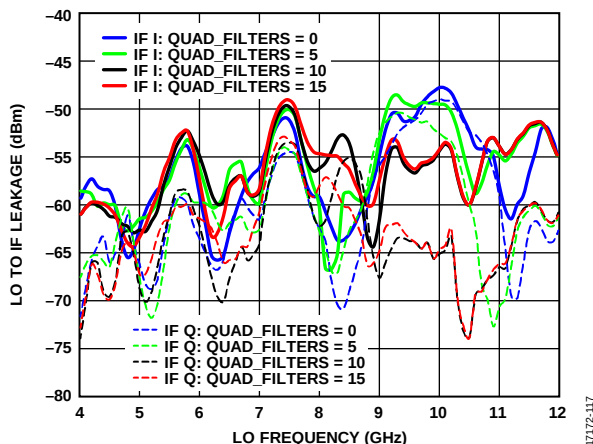


Figure 113. LO To IF Leakage vs. RF Frequency for Four Different QUAD_FILTERS Settings, $f_{IF} = 3.5$ GHz (Upper Sideband)

VVA TEMPERATURE COMPENSATION

Figure 114 shows the conversion gain vs. RF frequency at two different Register 0x0B settings and three different temperatures for IF mode. The recommended value suggested in the Start-Up Sequence section provides the highest conversion gain. If the priority is to decrease the conversion gain variation across temperature, Register 0x0B can be set to 0x726C. However, at this value, the conversion gain is lower at each temperature.

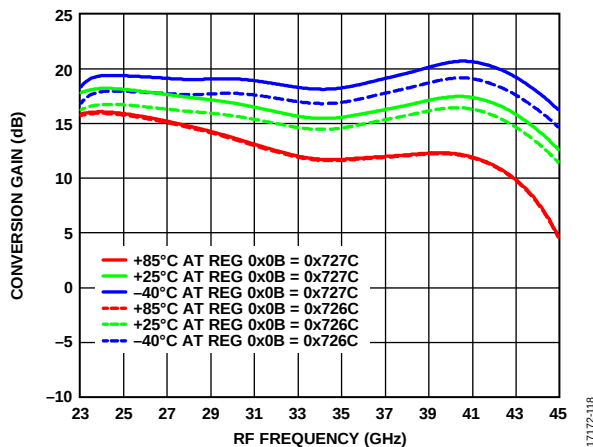


Figure 114. Conversion Gain vs. RF Frequency at Maximum Gain for Various Register 0x0B Settings and Various Temperatures

PERFORMANCE BETWEEN DIFFERENTIAL vs. SINGLE-ENDED LO INPUT

Figure 115 to Figure 117 show the conversion gain, input IP3 and image rejection performance for operating the ADMV1014 LO input as differential vs. SE. The measurements were performed with 0 dBm LO input power, IF mode, with an IF frequency of 3.5 GHz, upper sideband, and $T_A = 25^\circ\text{C}$.

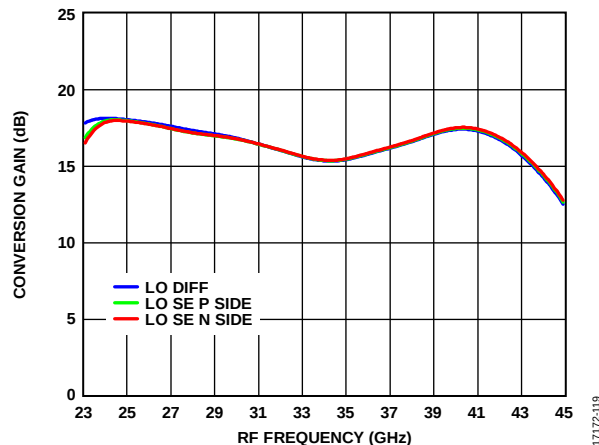


Figure 115. Conversion Gain vs. RF Frequency for Three Different LO Mode Settings, $f_{IF} = 3.5$ GHz (Upper Sideband)

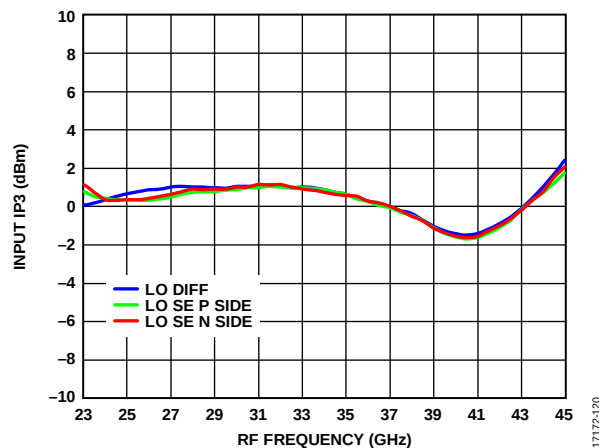


Figure 116. Input IP3 vs. RF Frequency for Three Different LO Mode Settings, RF Amplitude = -30 dBm per Tone at 20 MHz Spacing, $f_{IF} = 3.5$ GHz (Upper Sideband)

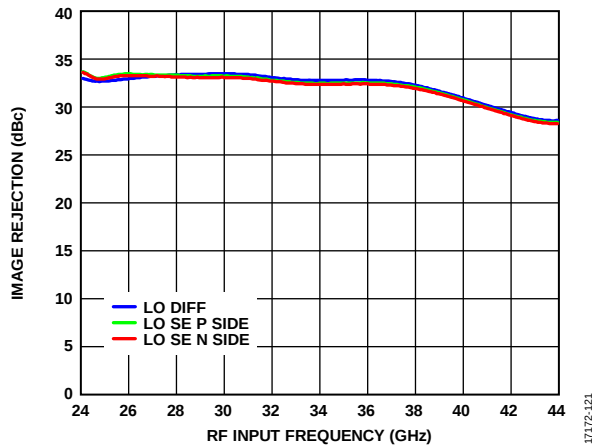


Figure 117. Image Rejection vs. RF Input Frequency for Three Different LO Mode Settings, RF Amplitude = -30 dBm per Tone at 20 MHz Spacing, $f_{IF} = 3.5$ GHz (Upper Sideband)

PERFORMANCE ACROSS RF FREQUENCY AT FIXED IF AND BASEBAND FREQUENCIES

The ADMV1014 quadrupler operates from 21.6 GHz to 41 GHz. When using high-side LO injection, the conversion gain starts rolling off gradually after the quadrupler frequency reaches 41 GHz. When using low-side LO, the conversion gain starts rolling off when the quadrupler frequency is 21.6 GHz.

Figure 118 and Figure 119 show the conversion gain vs. RF frequency in IF mode for fixed IF frequencies ($T_A = 25^\circ\text{C}$, LO = 6 dBm) for upper sideband and lower sideband, respectively. Figure 120 and Figure 121 show the conversion gain vs. RF frequency in IQ mode for fixed BB frequencies ($T_A = 25^\circ\text{C}$, LO = 6 dBm) for upper sideband and lower sideband, respectively.

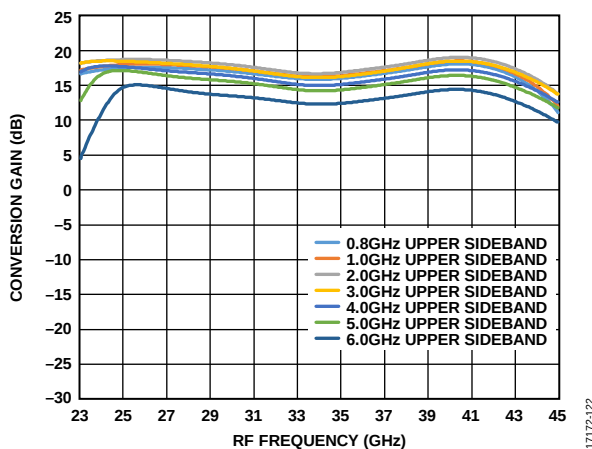


Figure 118. Conversion Gain vs. RF Frequency for Multiple IF Frequency Settings (Upper Sideband)

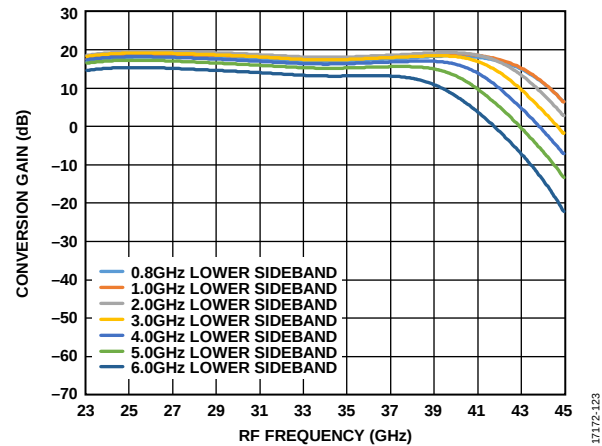


Figure 119. Conversion Gain vs. RF Frequency at Multiple IF Frequency Settings (Lower Sideband)

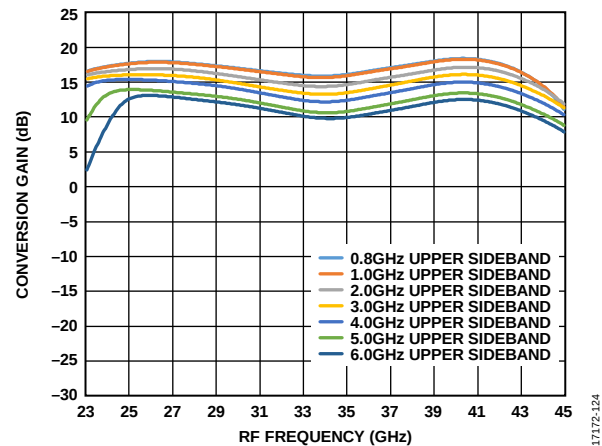


Figure 120. Conversion Gain vs. RF Frequency at Multiple I/Q Frequency Settings (Upper Sideband)

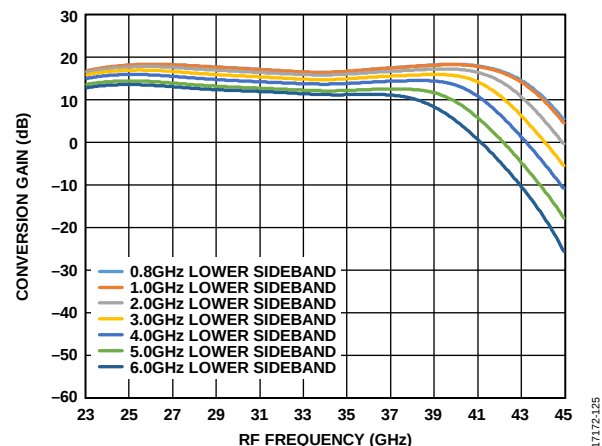


Figure 121. Conversion Gain vs. RF Frequency at Multiple IQ Frequency Settings (Lower Sideband)

RECOMMENDED LAND PATTERN

Solder the exposed pad on the underside of the ADMV1014 to a low thermal and electrical impedance ground plane. This pad is typically soldered to an exposed opening in the solder mask on the evaluation board. Connect these ground vias to all other ground layers on the evaluation board to maximize heat dissipation from the device package.

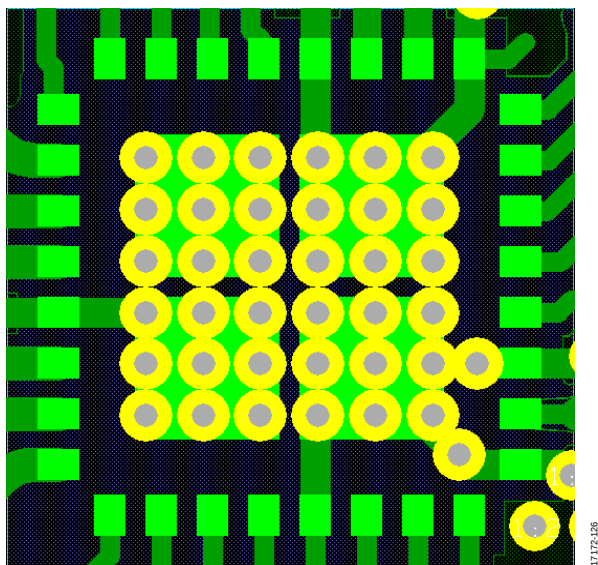


Figure 122. Evaluation Board Layout for the LGA package

EVALUATION BOARD INFORMATION

For more information about the ADMV1014 evaluation board, refer to the [ADMV1014-EVALZ](#) user guide.

REGISTER SUMMARY

Table 8. Register Summary

Reg.	Name	Bits	Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8	Reset	R/W		
			Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0				
0x00	SPI_CONTROL	[15:8]	PARITY_EN	SPI_SOFT_RESET	RESERVED		CHIP_ID[7:4]					0x0093	R/W	
		[7:0]	CHIP_ID[3:0]				REVISION							
0x01	ALARM	[15:8]	PARITY_ERROR	TOO_FEW_ERRORS	TOO_MANY_ERRORS	ADDRESS_RANGE_ERROR	RESERVED					0x0000	R	
		[7:0]	RESERVED											
0x02	ALARM_MASKS	[15:8]	PARITY_ERROR_MASK	TOO_FEW_ERRORS_MASK	TOO_MANY_ERRORS_MASK	ADDRESS_RANGE_ERROR_MASK	RESERVED					0xFFFF	R/W	
		[7:0]	RESERVED											
0x03	ENABLE	[15:8]	RESERVED	IBIAS_PD	P1DB_COMPENSATION		IF_AMP_PD	RESERVED	QUAD_BG_PD	BB_AMP_PD	0x0157	R/W		
		[7:0]	QUAD_IBIAS_PD	DET_EN	BG_PD	RESERVED								
0x04	QUAD	[15:8]	RESERVED						QUAD_SE_MODE[3:2]		0x5700	R/W		
		[7:0]	QUAD_SE_MODE[1:0]		RESERVED		QUAD_FILTERS							
0x05	LO_AMP_PHASE_ADJUST1	[15:8]	LOAMP_PH_ADJ_I_FINE								LOAMP_PH_ADJ_Q_FINE[6]	0x4101	R/W	
		[7:0]	LOAMP_PH_ADJ_Q_FINE[5:0]						RESERVED					
0x07	MIXER	[15:8]	MIXER_VGATE								RESERVED	0xD808	R/W	
		[7:0]	RESERVED	DET_PROG										
0x08	IF_AMP	[15:8]	RESERVED				IF_AMP_COARSE_GAIN_I				0x0000	R/W		
		[7:0]	IF_AMP_FINE_GAIN_Q				IF_AMP_FINE_GAIN_I							
0x09	IF_AMP_BB_AMP	[15:8]	IF_AMP_COARSE_GAIN_Q				RESERVED		BB_AMP_OFFSET_Q[4:3]		0x0000	R/W		
		[7:0]	BB_AMP_OFFSET_Q[2:0]			BB_AMP_OFFSET_I								
0x0A	BB_AMP__AGC	[15:8]	RESERVED										0x2390	R/W
		[7:0]	RESERVED	BB_AMP_REF_GEN				BB_AMP_GAIN_CTRL		BB_SWITCH_HIGH_LOW_COMMON_MODE				
0x0B	VVA_TEMP_COMP	[15:8]	VVA_TEMPERATURE_COMPENSATION[15:8]										0x4A5C	R/W
		[7:0]	VVA_TEMPERATURE_COMPENSATION[7:0]											

REGISTER DETAILS

Address: 0x00, Reset: 0x0093, Name: SPI_CONTROL

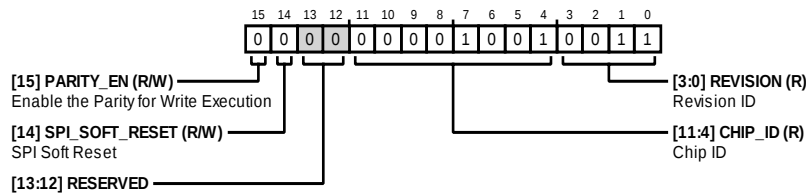


Table 9. Bit Descriptions for SPI_CONTROL

Bits	Bit Name	Settings	Description	Reset	Access
15	PARITY_EN		Enable the Parity for Write Execution	0x0	R/W
14	SPI_SOFT_RESET		SPI Soft Reset	0x0	R/W
[13:12]	RESERVED		Reserved	0x0	R
[11:4]	CHIP_ID		Chip ID	0x9	R
[3:0]	REVISION		Revision ID	0x3	R

Address: 0x01, Reset: 0x0000, Name: ALARM

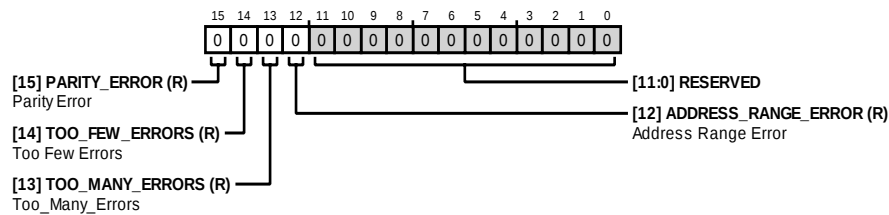


Table 10. Bit Descriptions for ALARM

Bits	Bit Name	Settings	Description	Reset	Access
15	PARITY_ERROR		Parity Error	0x0	R
14	TOO_FEW_ERRORS		Too Few Errors	0x0	R
13	TOO_MANY_ERRORS		Too Many Errors	0x0	R
12	ADDRESS_RANGE_ERROR		Address Range Error	0x0	R
[11:0]	RESERVED		Reserved	0x0	R

Address: 0x02, Reset: 0xFFFF, Name: ALARM_MASKS

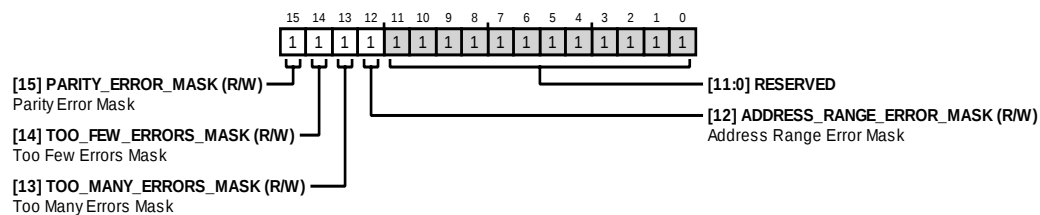


Table 11. Bit Descriptions for ALARM_MASKS

Bits	Bit Name	Settings	Description	Reset	Access
15	PARITY_ERROR_MASK		Parity Error Mask	0x1	R/W
14	TOO_FEW_ERRORS_MASK		Too Few Errors Mask	0x1	R/W
13	TOO_MANY_ERRORS_MASK		Too Many Errors Mask	0x1	R/W
12	ADDRESS_RANGE_ERROR_MASK		Address Range Error Mask	0x1	R/W
[11:0]	RESERVED		Reserved	0xFFF	R

Address: 0x03, Reset: 0x0157, Name: ENABLE

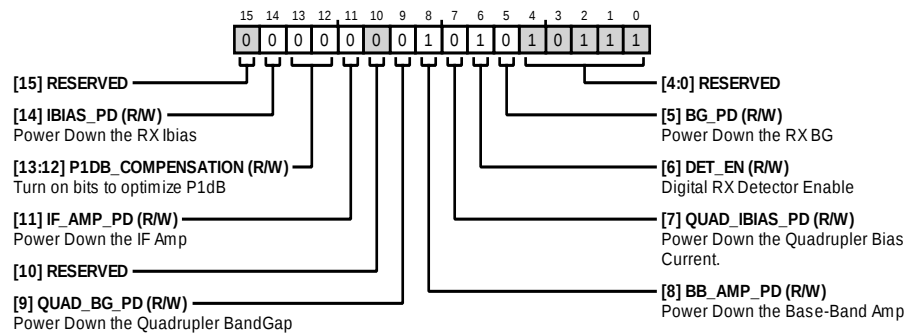


Table 12. Bit Descriptions for ENABLE

Bits	Bit Name	Settings	Description	Reset	Access
15	RESERVED		Reserved	0x0	R
14	IBIAS_PD		Power Down the Rx I _{BIAS}	0x0	R/W
[13:12]	P1DB_COMPENSATION		Turn on bits to optimize P1dB	0x0	R/W
11	IF_AMP_PD		Power Down the IF Amp	0x0	R/W
10	RESERVED		Reserved	0x0	R
9	QUAD_BG_PD		Power Down the Quadrupler Band Gap	0x0	R/W
8	BB_AMP_PD		Power Down the Baseband Amp	0x1	R/W
7	QUAD_IBIAS_PD		Power Down the Quadrupler Bias Current	0x0	R/W
6	DET_EN		Digital Rx Detector Enable	0x1	R/W
5	BG_PD		Power Down the Rx BG	0x0	R/W
[4:0]	RESERVED		Reserved	0x1	R

Address: 0x04, Reset: 0x5700, Name: QUAD

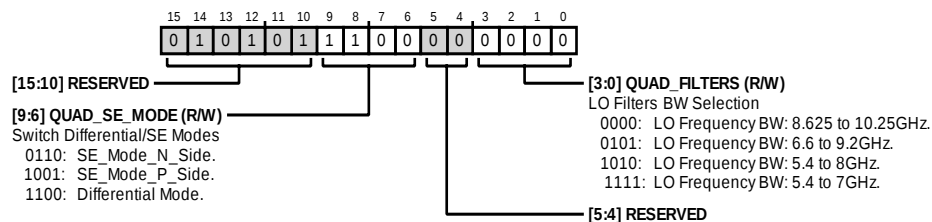


Table 13. Bit Descriptions for QUAD

Bits	Bit Name	Settings	Description	Reset	Access
[15:10]	RESERVED		Reserved	0x15	R
[9:6]	QUAD_SE_MODE	0110 1001 1100	Switch Differential/SE Modes SE Mode N Side SE Mode P Side Differential Mode	0xC	R/W
[5:4]	RESERVED		Reserved.	0x0	R
[3:0]	QUAD_FILTERS	0000 0101 1010 1111	LO Filters BW Selection LO Frequency BW: 8.625 GHz to 10.25 GHz LO Frequency BW: 6.6 GHz to 9.2 GHz LO Frequency BW: 5.4 GHz to 8 GHz LO Frequency BW: 5.4 GHz to 7 GHz	0x0	R/W

Address: 0x05, Reset: 0x4101, Name: LO_AMP_PHASE_ADJUST1

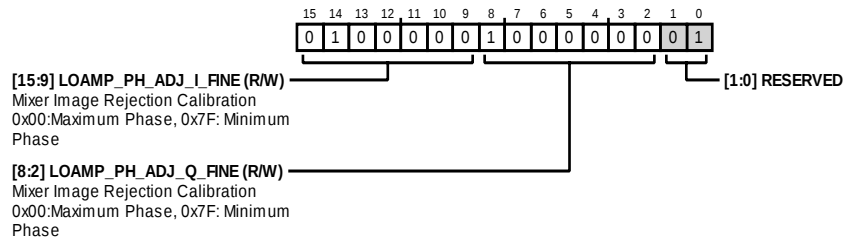


Table 14. Bit Descriptions for LO_AMP_PHASE_ADJUST1

Bits	Bit Name	Settings	Description	Reset	Access
[15:9]	LOAMP_PH_ADJ_I_FINE		Mixer Image Rejection Calibration 0x00: Maximum Phase, 0x7F: Minimum Phase	0x20	R/W
[8:2]	LOAMP_PH_ADJ_Q_FINE		Mixer Image Rejection Calibration 0x0: Maximum Phase, 0x7F: Minimum Phase	0x40	R/W
[1:0]	RESERVED		Reserved.	0x1	R

Address: 0x07, Reset: 0xD808, Name: MIXER

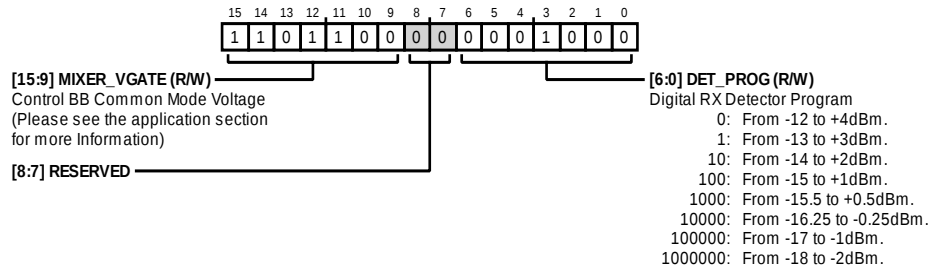


Table 15. Bit Descriptions for MIXER

Bits	Bit Name	Settings	Description	Reset	Access
[15:9]	MIXER_VGATE		Control BB Common Mode Voltage. See the Applications Information section for more information)	0x6C	R/W
[8:7]	RESERVED		Reserved.	0x0	R
[6:0]	DET_PROG		Digital Rx Detector Program. 0 From -12 dBm to +4 dBm. 1 From -13 dBm to +3 dBm. 10 From -14 dBm to +2 dBm. 100 From -15 dBm to +1 dBm. 1000 From -15.5 dBm to +0.5 dBm. 10000 From -16.25 dBm to -0.25 dBm. 100000 From -17 dBm to -1 dBm. 1000000 From -18 dBm to -2 dBm.	0x8	R/W

Address: 0x08, Reset: 0x0000, Name: IF_AMP

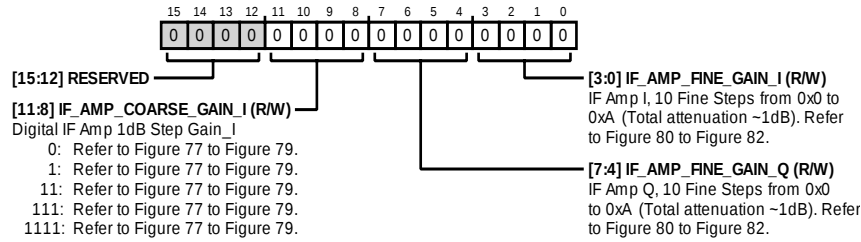


Table 16. Bit Descriptions for IF_AMP

Bits	Bit Name	Settings	Description	Reset	Access
[15:12]	RESERVED		Reserved.	0x0	R
[11:8]	IF_AMP_COARSE_GAIN_I	0 1 11 111 1111	Digital IF Amp Step Gain I. Refer to Figure 77 to Figure 79. Refer to Figure 77 to Figure 79. Refer to Figure 77 to Figure 79. Refer to Figure 77 to Figure 79. Refer to Figure 77 to Figure 79.	0x0	R/W
[7:4]	IF_AMP_FINE_GAIN_Q		IF Amp Q, 10 Fine Steps from 0x0 to 0xA. Refer to Figure 80 to Figure 82.	0x0	R/W
[3:0]	IF_AMP_FINE_GAIN_I		IF Amp I, 10 Fine Steps from 0x0 to 0xA. Refer to Figure 80 to Figure 82.	0x0	R/W

Address: 0x09, Reset: 0x0000, Name: IF_AMP_BB_AMP

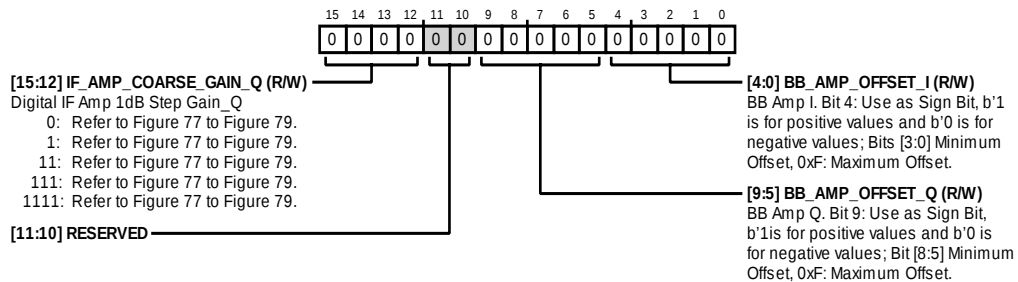


Table 17. Bit Descriptions for IF_AMP_BB_AMP

Bits	Bit Name	Settings	Description	Reset	Access
[15:12]	IF_AMP_COARSE_GAIN_Q	0 1 11 111 1111	Digital IF Amp 1 dB Step Gain Q Refer to Figure 77 to Figure 79 Refer to Figure 77 to Figure 79 Refer to Figure 77 to Figure 79 Refer to Figure 77 to Figure 79 Refer to Figure 77 to Figure 79	0x0	R/W
[11:10]	RESERVED		Reserved.	0x0	R
[9:5]	BB_AMP_OFFSET_Q		BB Amp Q (Bit 9: Use as Sign Bit, 1 is for positive values and 0 is for negative values; Bits[8:5]: Minimum Offset, 0xF: Maximum Offset)	0x0	R/W
[4:0]	BB_AMP_OFFSET_I		BB Amp I (Bit 4: Use as Sign Bit, 1 is for positive values and 0 is for negative values; Bits[3:0]: Minimum Offset, 0xF: Maximum Offset)	0x0	R/W

Address: 0x0A, Reset: 0x2390, Name: BB_AMP_AGC

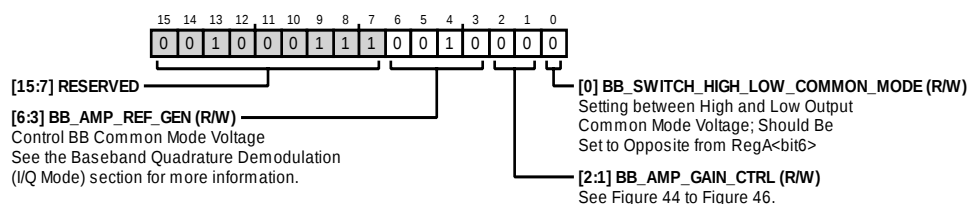


Table 18. Bit Descriptions for BB_AMP_AGC

Bits	Bit Name	Settings	Description	Reset	Access
[15:7]	RESERVED		Reserved.	0x4	R
[6:3]	BB_AMP_REF_GEN		Control BB Common-Mode Voltage. See the Baseband Quadrature Demodulation (I/Q Mode) section for more information.	0x2	R/W
[2:1]	BB_AMP_GAIN_CTRL		See Figure 44 to Figure 46.	0x0	R/W
0	BB_SWITCH_HIGH_LOW_COMMON_MODE		Setting between High and Low Output Common-Mode Voltage. This bit must bet to opposite from Register 0x0A, Bit 6. See the Baseband Quadrature Demodulation (I/Q Mode) section for more information.	0x0	R/W

Address: 0x0B, Reset: 0x4A5C, Name: VVA_TEMP_COMP

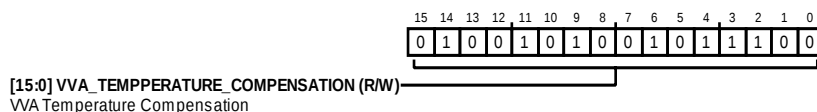
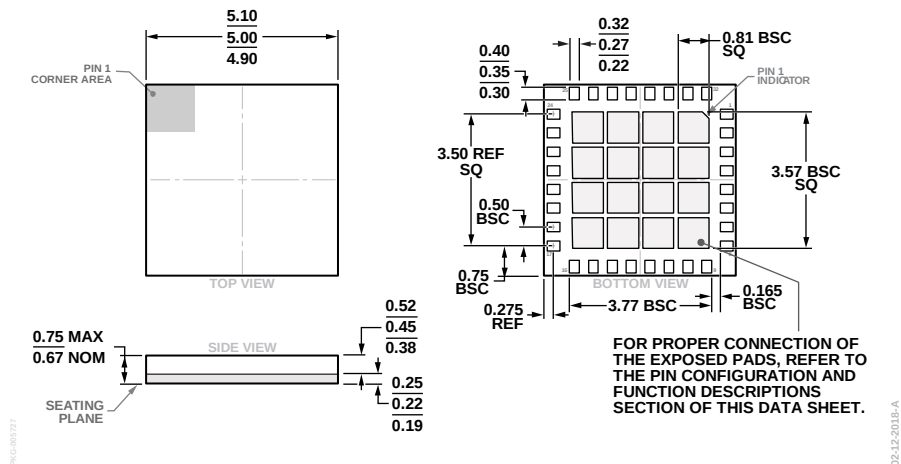


Table 19. Bit Descriptions for VVA_TEMP_COMP

Bits	Bit Name	Settings	Description	Reset	Access
[15:0]	VVA_TEMPERATURE_COMPENSATION		VVA Temperature Compensation. Set to 0x727C. See the Start-Up Sequence section and the VVA Temperature Compensation section for more information.	0x4A5C	R/W

OUTLINE DIMENSIONS



ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option
ADMV1014ACCZ	−40°C to +85°C	32-Terminal Land Grid Array Package [LGA]	CC-32-6
ADMV1014ACCZ-R7	−40°C to +85°C	32-Terminal Land Grid Array Package [LGA]	CC-32-6
ADMV1014-EVALZ		Evaluation Board	

¹ Z = RoHS-Compliant Part.